

# **PCTEST**

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# **HEARING AID COMPATIBILITY**

**Applicant Name:** 

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

**Date of Testing:** 07/13/2020 - 08/02/2020 **Test Site/Location:** PCTEST, Columbia, MD, USA **Test Report Serial No.:** 1M2005200087-19-R1.A3L Date of Issue: 08/15/2020

FCC ID: A3LSMF916U

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: RF Emissions Testing

Application Type: Certification FCC Rule Part(s): CFR §20.19(b) **HAC Standard:** ANSI C63.19-2011

CTIA Test Plan for Hearing Aid Compatibility Rev 3.1.1, May 2017

285076 D01 HAC Guidance v05

285076 D02 T-Coil testing for CMRS IP v03

**DUT Type:** Portable Handset Model: SM-F916U

Additional Model(s): SM-F916U1. SM-F916W

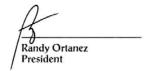
**Test Device Serial No.:** Pre-Production Sample [S/N: 1113M]

C63.19-2011 HAC Category: **M4 (RF EMISSIONS CATEGORY)** 

Note: This revised Test Report (S/N: 1M2005200087-19-R1.A3L) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested. North America bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.





Authorized Lab Code: 20080603-00





FCC ID: A3LSMF916U	PCTEST .  Road to be post of \$\infty\$ exceeds	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 1 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 1 of 101

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# TABLE OF CONTENTS

1.	INTRODUCTION	3
2.	DUT DESCRIPTION	4
3.	ANSI/IEEE C63.19 PERFORMANCE CATEGORIES	7
4.	SYSTEM SPECIFICATIONS	8
5.	TEST PROCEDURE	13
6.	SYSTEM CHECK	15
7.	MODULATION INTERFERENCE FACTOR	18
8.	RF CONDUCTED POWER MEASUREMENTS	30
9.	JUSTIFICATION OF HELD TO EAR MODES TESTED	40
10.	LTE TDD UPLINK-DOWNLINK CONFIGURATION	42
11.	OVERALL MEASUREMENT SUMMARY	44
12.	EQUIPMENT LIST	48
13.	MEASUREMENT UNCERTAINTY	49
14.	TEST DATA	50
15.	CALIBRATION CERTIFICATES	65
16.	CONCLUSION	96
17.	REFERENCES	97
18.	TEST PHOTOGRAPHS	99

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dog 2 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 2 of 101

#### 1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-86581 to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

# Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

<sup>&</sup>lt;sup>1</sup> FCC Rule & Order, WT Docket 01-309 RM-8658

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 3 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 3 01 101

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# 2. DUT DESCRIPTION



FCC ID: A3LSMF916U

Manufacturer: Samsung Electronics Co., Ltd.

129, Samsung-ro, Maetan dong,

Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Model: SM-F916U

Additional Model(s): SM-F916U1, SM-F916W

Serial Number: 1113M

Antenna Configurations: Internal Antenna
DUT Type: Portable Handset

### I. Power Reduction for WIFI

This device uses an independent fixed level power reduction mechanism for all WIFI operations during voice or VoIP held to ear scenarios. Reduced powers were used to evaluate for low-power exemption in Section 9.II for WIFI. Detailed descriptions of the power reduction mechanism are included in the operational description.

### II. LTE Band Selection

This device supports the following pair of LTE bands with similar frequencies: LTE B66 & B4. This pair of LTE bands has the same target power and shares the same transmission path. Since the supported frequency span for the smaller LTE band is completely covered by the larger LTE band, only the larger LTE band (LTE B66) was evaluated for hearing-aid compliance. LTE B5 and B2 are LTE anchor bands for dual connectivity (EN-DC) scenarios between LTE and NR so they were additionally evaluated as independent LTE bands.

### III. NR Band Selection

This device supports the following pair of NR bands with similar frequencies: NR n25 & n2. This pair of NR bands has the same target power and shares the same transmission path. Since the supported frequency span for the smaller NR band is completely covered by the larger NR band, only the larger NR band (n25) was evaluated for hearing-aid compliance.

### IV. Antenna Diversity Transmission

The following modes support transmission from a secondary TX antenna (Ant B): GSM 850, CDMA Band Class 0, LTE Band 13, and LTE Band 14. The worst-case configurations from these modes were additionally evaluated using Ant B to ensure the primary antenna transmission (Ant A), was the worst case.

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 4 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 4 of 101

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# Table 2-1 SM-F916U & SM-F916U1 HAC Air Interfaces

			C	F91601 HAC All Interfaces		
Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Name of Voice Service	
	835	1/0	V	Vers MIEL en DT	CMDC Voice	
CDMA	1900	VO	Yes	Yes: WIFI or BT	CMRS Voice	
	EvDO	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo	
	850	VO	Yes	Yes: WIFI or BT	CMRS Voice	
GSM	1900	VO	res	res. Wiri Oi Bi		
	GPRS/EDGE	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo	
	850					
UMTS	1700	VD	No <sup>1</sup>	Yes: WIFI or BT	CMRS Voice	
UIVITS	1900					
	HSPA	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo	
	680 (B71)		No <sup>1 2</sup>			
	700 (B12)					
	780 (B13)					
	790 (B14)			Yes: WIFI or BT		
	850 (B5)	1	No <sup>1</sup>			
	850 (B26)					
LTE (FDD)	1700 (B4)	VD			VoLTE, Google Duo	
	1700 (B66)					
	1900 (B2)					
	1900 (B25)					
	2300 (B30)					
	2500 (B7)					
	2600 (B41)					
LTE (TDD)	3600 (B48)	VD	Yes	Yes: WIFI or BT	VoLTE, Google Duo	
	680 (n71)		No <sup>1 2</sup>			
	850 (n5)					
NR (FDD)	1700 (n66)	VD		Yes: WIFI or BT	Google Duo	
	1900 (n2)		No <sup>1</sup>			
	1900 (n25)					
	2600 (n41)		Yes			
NR (TDD)	28000 (n261)	VD	N1 . 3	Yes: WIFI or BT	Google Duo	
	39000 (n260)		No <sup>3</sup>			
	2450					
	5200 (U-NII 1)					
WIFI	5300 (U-NII 2A)	VD	No <sup>1</sup>	Yes: CDMA, GSM, UMTS, LTE, or NR	VoWIFI, Google Duo	
	5500 (U-NII 2C)					
	5800 (U-NII 3)					
ВТ	2450	DT	No	Yes: CDMA, GSM, UMTS, LTE, or NR	N/A	
_			2. LTE B71 and additionally to equipment.	or MIF and low-power exemption. I NR n71, while outside the scope of ANSI C63.19 ested according to the existing HAC procedures w	rith currently available test	
			5. 11200 allu II.	Lot are currently outside the scope of ANSI Cos.	o and rec fine regulations therefore	

3. n260 and n261 are currently outside the scope of ANSI C63.19 and FCC HAC regulations therefore they were not evaluated.

FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 5 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 5 01 101

# Table 2-2 SM-F916W HAC Air Interfaces

Air-Interface	Band	Type Transport	HAC Tested	Simultaneous	Name of Voice Service
7	(MHz)	.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		But Not Tested	144
CDMA	835	VO	Yes	Yes: WIFI or BT	CMRS Voice
CDMA	EvDO	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	850	VO	Yes	Yes: WIFI or BT	CMRS Voice
GSM	1900	VO	163	res. Wiri Oi Bi	CIVINS VOICE
	GPRS/EDGE	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	850				
UMTS	1700	VD	No <sup>1</sup>	Yes: WIFI or BT	CMRS Voice
OWITS	1900				
	HSPA	VD	No <sup>1</sup>	Yes: WIFI or BT	Google Duo
	680 (B71)		No <sup>1 2</sup>	No <sup>1 2</sup> Yes: WIFI or BT	
	700 (B12)				
	780 (B13)	VD	No <sup>1</sup>		VolTE, Google Duo
LTE (FDD)	850 (B5)				
	1700 (B4)				
	1700 (B66)				VOLTE, Google Duo
	1900 (B2)				
	1900 (B25)				
	2300 (B30)				
	2500 (B7)				
LTE (TDD)	2600 (B41)	VD	Yes	Yes: WIFI or BT	VoLTE, Google Duo
NR (FDD)	680 (n71)	VD	No <sup>1 2</sup>	Yes: WIFI or BT	Google Duo
WK (FDD)	1700 (n66)	VD	No <sup>1</sup>	res. Will of Bi	Google Duo
NR (TDD)	2600 (n41)	VD	Yes	Yes: WIFI or BT	Google Duo
	2450				
	5200 (U-NII 1)				
WIFI	5300 (U-NII 2A)	VD	No <sup>1</sup>	Yes: CDMA, GSM, UMTS, LTE, or NR	VoWIFI, Google Duo
	5500 (U-NII 2C)				
	5800 (U-NII 3)				
BT	2450	DT	No	Yes: CDMA, GSM, UMTS, LTE, or NR	N/A
VO = Voice Only DT = Digital Data - Not intended for Voice Services  1. Evaluation   2. LTE I			2. LTE B71 and	or MIF and low-power exemption. I NR n71, while outside the scope of ANSI C63.19 ested according to the existing HAC procedures w	<u> </u>

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 6 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 6 of 101

# 3. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

# I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters			
Near field Category	E-field emissions CW dB(V/m)			
	f < 960 MHz			
M1	50 to 55			
M2	45 to 50			
M3	40 to 45			
M4	< 40			
	f > 960 MHz			
M1	40 to 45			
M2	35 to 40			
М3	30 to 35			
M4	< 30			
Table 3-1 WD near-field categories as defined in ANSI C63.19-2011				

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 7 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 7 of 101

# 4. SYSTEM SPECIFICATIONS

# **EF3DV3 E-Field Probe Description**

Construction: One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

Calibration: In air from 30 MHz to 6.0 GHz

(absolute accuracy ±5.1%, k=2)

Frequency: 30 MHz to > 6 GHz;

Linearity: ± 0.2 dB (30 MHz to 6 GHz)

Directivity  $\pm 0.2 \text{ dB}$  in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m

(M3 or better device readings fall well below diode

compression point)

Linearity: ± 0.2 dB

Dimensions Overall length: 337 mm (Tip: 20 mm)

Tip diameter: 4.0 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 1.5 mm



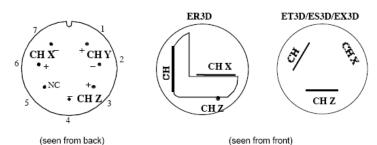
Figure 4-1 E-field Free-space Probe

## **Probe Tip Description**

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement").

# Connector Plan



The antistatic shielding inside the probe is connected to the probe connector case.

FCC ID: A3LSMF916U	PCTEST HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 8 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage o or io i

# **Equation 1**

# Conversion of Connector Voltage u, to E-Field E,

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

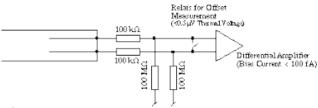
E<sub>i</sub>: electric field in V/m

 $u_i$ : voltage of channel i at the connector in  $\mu V$ Norm: sensitivity of channel i in  $\mu V/(V/m)^2$ enhancement factor in liquid (ConvF=1 for Air)

DCP: diode compression point in  $\mu V$ 

CF: signal crest factor (peak power/average power)

## **Conditions of Calibration**

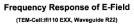


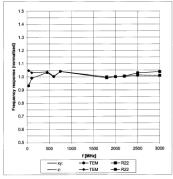
Please note:

- a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
- · larger bias currents will cause higher offset

# **Probe Response to Frequency**

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).





Uncertainty of Frequency Response of E-field: ± 6.3% (k=

Figure 4-2 E-Field Probe Frequency Response

FCC ID: A3LSMF916U	PCTEST HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 0 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 9 of 101

### **SPEAG Robotic System**

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



**Figure 4-3** SPEAG Robotic System

### **System Hardware**

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

FCC ID: A3LSMF916U	PCTEST: HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 10 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 10 of 101

### **System Electronics**

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

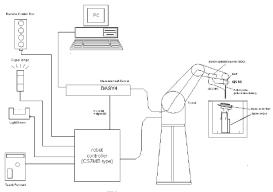


Figure 4-4 SPEAG Robotic System Diagram

### **DASY5 Instrumentation Chain**

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$\begin{aligned} V_i &= U_i + U_i^2 \cdot \frac{cf}{dcp_i} \\ \text{with} \quad V_i &= \text{compensated signal of channel i} & (i = x, y, z) \\ U_i &= \text{input signal of channel i} & (i = x, y, z) \\ cf &= \text{crest factor of exciting field} & (\text{DASY parameter}) \\ dcp_i &= \text{diode compression point} & (\text{DASY parameter}) \end{aligned}$$

FCC ID: A3LSMF916U	PCTEST:  HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 11 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 1101101

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From the compensated input signals the primary field data for each channel can be evaluated:

E – field  
probes : 
$$E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with  $V_i$  = compensated signal of channel i (i = x, y, z)  $Norm_i$  = sensor sensitivity of channel i (i = x, y, z)

 $\mu V/(V/m)^2$  for E-field Probes

ConvF = sensitivity enhancement in solution

 $E_i$  = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

### **Environmental Conditions**

Environmental conditions such as temperature and relative humidity are monitored to ensure there are no impacts on system specifications. Proper voltage and power line frequency conditions are maintained with three phase power sources. Environmental noise and reflections are monitored through system checks.

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 10 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 12 of 101

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# 5. TEST PROCEDURE

## I. RF EMISSIONS

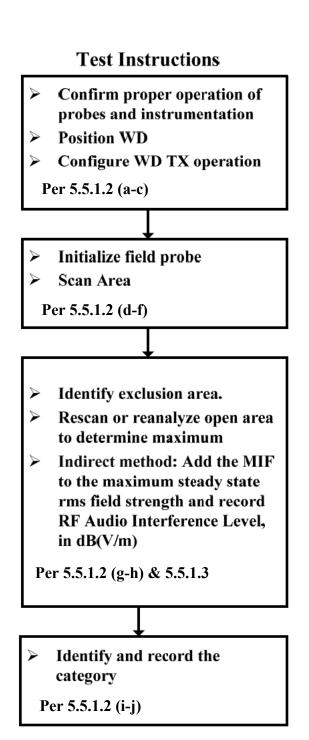


Figure 5-1 RF Emissions Flow Chart

	_			
FCC ID: A3LSMF916U	PCTEST:	HAC (RF EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 13 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 13 01 101

## **Test Setup**

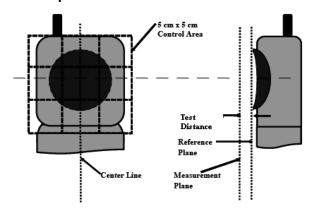


Figure 5-2
E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

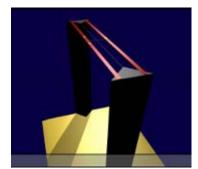


Figure 5-3 HAC Phantom

### **RF Emissions Test Procedure:**

The following illustrate a typical RF emissions test scan over a wireless communications device:

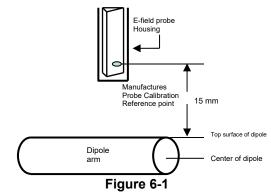
- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. Of the 9 subgrids (see Figure 5-2), 3 contiguous subgrids may be excluded from the measurement in order to account for localized areas of higher field intensities. The center subgrid containing the acoustic output or audio band magnetic output may not excluded. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

FCC ID: A3LSMF916U	PCTEST HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dog 14 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 14 of 101

# I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

# II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

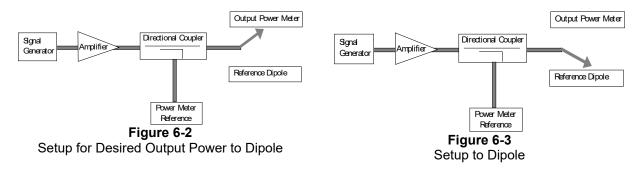
## **Measurement of CW**

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 15 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 15 of 101

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RF power was recorded using both an average and a peak power reading meter.



Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 6-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



2-D Raw Data from scan along dipole axis

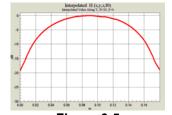
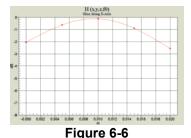


Figure 6-5
2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along transverse axis

FCC ID: A3LSMF916U	PCTEST .  Road to be post of § secured.	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 16 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 16 of 101

# **III. System Check Results**

# **Validation Results**

Date	Frequency (MHz)	Probe S/N	DAE S/N	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation	
7/13/2020	835			1003	20.0	111.5	105.2	5.9%	
1/13/2020	1880			1137	20.0	90.7	87.8	3.3%	
7/27/2020	1000	4005	665	CCE	1137	20.0	91.9	87.8	4.6%
7/13/2020	2600	4035		4040	20.0	88.3	85.2	3.7%	
7/27/2020	2000			1012	20.0	87.8	85.2	3.1%	
7/27/2020	3500			1005	20.0	87.9	84.1	4.6%	

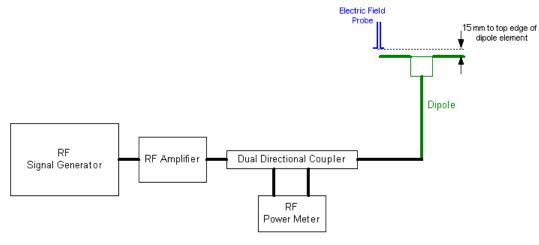


Figure 6-8 System Check Setup

FCC ID: A3LSMF916U	PCTEST hould to be part of the second	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 17 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 17 01 101

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### **MODULATION INTERFERENCE FACTOR** 7.

# I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No.: 1010:

- 1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
- 2. The device was then set to continuously transmit at maximum power.
- 3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
- 4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
- Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

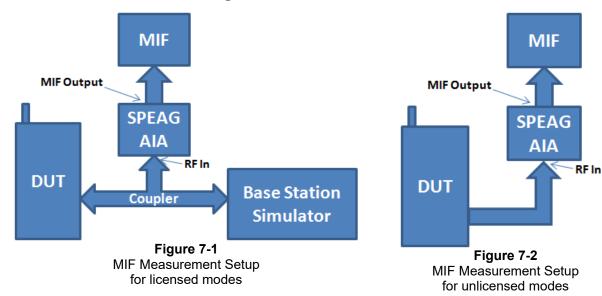
### Audio Interference Level [dB(V/m)] = 20 \* log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 18 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 10 01 101

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# II. MIF Measurement Block Diagrams



# **III. Measured Modulation Interference Factors:**

**Table 7-1**CDMA Modulation Interference Factors<sup>1</sup>

OBINIT INICIALIAN INICIALIST INICIALIST ACCORD								
	Cell				PCS			
Mo	ode	908	22H	22H	22H	24E	24E	24E
		564	1013	384	777	25	600	1175
	RC1/SO3	3.00	3.03	3.00	3.04	2.89	2.82	2.81
CDMA	RC1/SO55	-19.73	-19.81	-19.72	-19.71	-19.93	-19.83	-19.94
	EvDO	-19.10	-19.12	-19.14	-19.05	-19.04	-19.24	-19.42

**Table 7-2**GSM Modulation Interference Factors<sup>1</sup>

Mc	Mode		GSM850		GSM1900			
		128	190	251	512	661	810	
GSM	Voice	3.52	3.53	3.53	3.51	3.51	3.51	
GSIVI	EDGE	3.63	3.68	3.67	3.50	3.52	3.52	

**Table 7-3**UMTS Modulation Interference Factors<sup>1</sup>

	Civit o inicaliation interference i actors											
Mode			UMTS V			UMTS IV		UMTS II				
		4132	4183	4233	1312	1412	1513	9262	9400	9538		
	12.2 kbps RMC	-24.28	-24.41	-24.27	-24.43	-24.77	-24.72	-24.46	-24.85	-24.39		
UMTS	12.2 kbps AMR	-14.23	-13.54	-13.48	-13.66	-13.98	-13.69	-13.66	-13.63	-13.72		
	HSUPA Subtest1	-23.53	-23.33	-23.57	-23.00	-23.14	-23.98	-23.73	-23.68	-23.75		

<sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

FCC ID: A3LSMF916U	POTEST: Proud to be post of the resources	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 10 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 19 of 101

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**Table 7-4**LTE FDD Modulation Interference Factors<sup>1,2,3</sup>

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
71	680.5	133297	20	16QAM	1	0	-10.21
66	1745.0	132322	20	16QAM	1	0	-10.02
2	1880.0	18900	20	16QAM	1	0	-10.06
25	1882.5	26365	20	16QAM	1	0	-10.19
7	2535.0	21100	20	16QAM	1	0	-10.43
26	831.5	26865	15	16QAM	1	0	-9.58
12	707.5	23095	10	16QAM	1	0	-9.67
13	782.0	23230	10	16QAM	1	0	-10.32
14	793.0	23330	10	16QAM	1	0	-10.44
5	836.5	20525	10	16QAM	1	0	-9.88
30	2310.0	27710	10	16QAM	1	0	-9.96
26	831.5	26865	15	QPSK	1	0	-13.99
26	831.5	26865	15	64QAM	1	0	-9.34
26	831.5	26865	15	256QAM	1	0	-9.72
26	831.5	26865	15	64QAM	1	36	-9.12
26	831.5	26865	15	64QAM	1	74	-9.13
26	831.5	26865	15	64QAM	36	0	-17.17
26	831.5	26865	15	64QAM	75	0	-18.56
26	831.5	26865	10	64QAM	1	25	-9.37
26	831.5	26865	5	64QAM	1	12	-9.72
26	831.5	26865	3	64QAM	1	7	-9.50
26	831.5	26865	1.4	64QAM	1	3	-9.37

**Table 7-5**LTE FDD Uplink Carrier Aggregation Modulation Interference Factor<sup>1,4</sup>

				PCC							scc				
Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL) Channel	PCC (UL) Frequency [MHz]	Modulation	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL) Channel	SCC (UL) Frequency [MHz]	Modulation	SCC UL# RB	SCC UL RB Offset	MIF (dB)
CA_5B	LTE B5	10	20525	836.5	16QAM	1	0	LTE B5	5	20453	829.3	16QAM	1	24	-10.14
CA_66B	LTE B66	10	132322	1745.0	16QAM	1	0	LTE B66	10	132223	1735.1	16QAM	1	49	-10.17
CA_66C	LTE B66	20	132322	1745.0	16QAM	1	0	LTE B66	20	132124	1725.2	16qAM	1	99	-9.81

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>4</sup> Note: LTE FDD ULCA was evaluated to ensure LTE FDD standalone was the worst-case scenario. The configurations in Table 7-5 were determined from Table 7-4 and satisfy the configuration requirements as defined in 3GPP 36.101.

FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 20 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 20 01 101

<sup>&</sup>lt;sup>2</sup> Note: All FDD LTE bands were found to have substantially similar MIF values given similar RB, BW, and modulation configurations.

<sup>&</sup>lt;sup>3</sup> Note: Since LTE Band 26 at 15MHz bandwidth is the overall worst-case LTE FDD MIF and does not support 3 non-overlapping channels, MIF measurements were made only on the middle channel.

Table 7-6 LTE TDD B41 Power Class 3 Modulation Interference Factors<sup>1,2</sup>

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	3.53
41	2593.0	40620	20	QPSK	1	0	3.48
41	2593.0	40620	20	64QAM	1	0	3.48
41	2593.0	40620	20	256QAM	1	0	3.13
41	2593.0	40620	20	16QAM	1	50	3.56
41	2593.0	40620	20	16QAM	1	99	3.54
41	2593.0	40620	20	16QAM	50	0	3.36
41	2593.0	40620	20	16QAM	100	0	3.37
41	2593.0	40620	15	16QAM	1	36	3.26
41	2593.0	40620	10	16QAM	1	25	3.67
41	2593.0	40620	5	16QAM	1	12	3.56
41	2506.0	39750	10	16QAM	1	25	3.58
41	2549.5	40185	10	16QAM	1	25	3.40
41	2636.5	41055	10	16QAM	1	25	3.69
41	2680.0	41490	10	16QAM	1	25	3.58

Table 7-7 LTE TDD B41 Power Class 2 Modulation Interference Factors<sup>1,3</sup>

		יידע ט	JI CIASS Z IVI	odulation ini	CHOICHOC I	401013	
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	1.53
41	2593.0	40620	20	QPSK	1	0	1.45
41	2593.0	40620	20	64QAM	1	0	1.52
41	2593.0	40620	20	256QAM	1	0	1.39
41	2593.0	40620	20	16QAM	1	50	1.52
41	2593.0	40620	20	16QAM	1	99	1.52
41	2593.0	40620	20	16QAM	50	0	1.37
41	2593.0	40620	20	16QAM	100	0	1.38
41	2593.0	40620	15	16QAM	1	0	1.57
41	2593.0	40620	10	16QAM	1	0	1.54
41	2593.0	40620	5	16QAM	1	0	1.48
41	2506.0	39750	15	16QAM	1	0	1.46
41	2549.5	40185	15	16QAM	1	0	1.41
41	2636.5	41055	15	16QAM	1	0	1.57
41	2680.0	41490	15	16QAM	1	0	1.46

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>3</sup> Note: LTE TDD Power Class 2 MIFs were taken using UL-DL Configuration 2. More information about the chosen UL-DL Configuration can be found in Section 10.

FCC ID: A3LSMF916U	PCTEST:	IAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 24 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 21 of 101

<sup>&</sup>lt;sup>2</sup> Note: LTE TDD Power Class 3 MIFs were taken using UL-DL Configuration 5. More information about the chosen UL-DL Configuration can be found in Section 10.

**Table 7-8**LTE TDD B48 Modulation Interference Factors<sup>1,2</sup>

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
48	3625.0	55990	20	16QAM	1	0	3.56
48	3625.0	55990	20	QPSK	1	0	3.55
48	3625.0	55990	20	64QAM	1	0	3.41
48	3625.0	55990	20	256QAM	1	0	3.16
48	3625.0	55990	20	16QAM	1	50	3.32
48	3625.0	55990	20	16QAM	1	99	3.31
48	3625.0	55990	20	16QAM	50	0	3.41
48	3625.0	55990	20	16QAM	100	0	3.40
48	3625.0	55990	15	16QAM	1	0	3.49
48	3625.0	55990	10	16QAM	1	0	3.54
48	3625.0	55990	5	16QAM	1	0	3.57
48	3552.5	55265	5	16QAM	1	0	3.52
48	3697.5	56715	5	16QAM	1	0	3.58

**Table 7-9**LTE TDD Uplink Carrier Aggregation Modulation Interference Factor<sup>1,3</sup>

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				PCC				SCC							
Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL/DL) Channel	PCC (UL/DL) Frequency [MHz]	Modulation	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL/DL) Channel	SCC (UL/DL) Frequency [MHz]		SCC UL# RB	SCC UL RB Offset	MIF (dB)
CA_41C (PC3)	LTE B41	20	40620	2593.0	16QAM	1	0	LTE B41	20	40422	2573.2	16QAM	1	99	3.43
CA_41C (PC2)	LTE B41	20	40620	2593.0	16QAM	1	0	LTE B41	20	40422	2573.2	16QAM	1	99	1.43
CA_48C	LTE B48	20	55773	2593.0	16QAM	1	0	LTE B41	20	55575	2573.2	16QAM	1	99	3.46

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

FCC ID: A3LSMF916U	POTEST: Road to be post of the second HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 22 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 22 of 101

<sup>&</sup>lt;sup>2</sup> Note: LTE TDD B48 MIFs were taken using UL-DL Configuration 5. More information about the chosen UL-DL Configuration can be found in Section 10.

<sup>&</sup>lt;sup>3</sup> Note: LTE TDD ULCA was evaluated to ensure LTE TDD standalone was the worst-case scenario. The configuration in Table 7-9 was determined from Tables 7-6 to 7-8 and satisfies the configuration requirements as defined in 3GPP 36.101. These MIFs were evaluated with UL-DL Configuration 5 for Power Class 3 LTE TDD and UL-DL Configuration 2 for Power Class 2 LTE TDD.

**Table 7-10**NR FDD Modulation Interference Factors<sup>1,2</sup>

NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]
n5	836.5	167300	20	DFT-s-OFDM	16QAM	1	1	-14.65
n71	680.5	136100	20	DFT-s-OFDM	16QAM	1	1	-15.22
n66	1745.0	34900	20	DFT-s-OFDM	16QAM	1	1	-11.75
n25	1882.5	376500	20	DFT-s-OFDM	16QAM	1	1	-11.71
n25	1882.5	376500	20	DFT-s-OFDM	64QAM	1	1	-10.58
n25	1882.5	376500	20	DFT-s-OFDM	256QAM	1	1	-11.88
n25	1882.5	376500	20	DFT-s-OFDM	QPSK	1	1	-17.68
n25	1882.5	376500	20	DFT-s-OFDM	π/2-BPSK	1	1	-19.01
n25	1882.5	376500	20	CP-OFDM	16QAM	1	1	-11.60
n25	1882.5	376500	20	CP-OFDM	64QAM	1	1	-11.38
n25	1882.5	376500	20	CP-OFDM	256QAM	1	1	-14.03
n25	1882.5	376500	20	CP-OFDM	QPSK	1	1	-16.22
n25	1882.5	376500	20	DFT-s-OFDM	64QAM	1	53	-10.34
n25	1882.5	376500	20	DFT-s-OFDM	64QAM	1	104	-10.46
n25	1882.5	376500	20	DFT-s-OFDM	64QAM	50	0	-16.37
n25	1882.5	376500	20	DFT-s-OFDM	64QAM	100	0	-17.84
n25	1882.5	376500	15	DFT-s-OFDM	64QAM	1	40	-10.34
n25	1882.5	376500	10	DFT-s-OFDM	64QAM	1	26	-10.27
n25	1882.5	376500	5	DFT-s-OFDM	64QAM	1	13	-10.34
n25	1855.0	371000	10	DFT-s-OFDM	64QAM	1	26	-10.09
n25	1910.0	382000	10	DFT-s-OFDM	64QAM	1	26	-10.06

**Table 7-11**NR TDD Modulation Interference Factors<sup>1</sup>

NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]
n41	2593.0	518598	100	DFT-s-OFDM	QPSK	1	1	1.30
n41	2593.0	518598	100	DFT-s-OFDM	π/2-BPSK	1	1	1.31
n41	2593.0	518598	100	DFT-s-OFDM	16QAM	1	1	1.18
n41	2593.0	518598	100	DFT-s-OFDM	64QAM	1	1	1.20
n41	2593.0	518598	100	DFT-s-OFDM	256QAM	1	1	1.16
n41	2593.0	518598	100	CP-OFDM	16QAM	1	1	1.17
n41	2593.0	518598	100	CP-OFDM	QPSK	1	1	1.19
n41	2593.0	518598	100	CP-OFDM	64QAM	1	1	1.07
n41	2593.0	518598	100	CP-OFDM	256QAM	1	1	0.99
n41	2593.0	518598	100	DFT-s-OFDM	π/2-BPSK	1	137	1.32
n41	2593.0	518598	100	DFT-s-OFDM	π/2-BPSK	1	271	1.24
n41	2593.0	518598	100	DFT-s-OFDM	π/2-BPSK	135	0	1.33
n41	2593.0	518598	100	DFT-s-OFDM	π/2-BPSK	270	0	1.34
n41	2593.0	518598	90	DFT-s-OFDM	π/2-BPSK	243	0	1.32
n41	2593.0	518598	80	DFT-s-OFDM	π/2-BPSK	216	0	1.33
n41	2593.0	518598	60	DFT-s-OFDM	π/2-BPSK	162	0	1.33
n41	2593.0	518598	50	DFT-s-OFDM	π/2-BPSK	128	0	1.30
n41	2593.0	518598	40	DFT-s-OFDM	π/2-BPSK	100	0	1.30
n41	2593.0	518598	20	DFT-s-OFDM	π/2-BPSK	50	0	1.30

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>2</sup> Note: All FDD NR bands were found to have substantially similar MIF values given similar RB, BW, and modulation configurations.

FCC ID: A3LSMF916U	PCTEST Final to be just of the seasons	IAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 23 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Faye 23 01 101

802.11b (2.4GHz, SISO) Modulation Interference Factors<sup>1,2</sup>

	802.11b MIF Measurements [dB]							
Mode	Data Rate [Mbps]							
	1	2	5.5	11				
802.11b	-9.85	-8.99	-6.99	-5.86				

### **Table 7-13**

802.11b (2.4GHz, MIMO) Modulation Interference Factors<sup>1,2</sup>

	802.11b MIF Measurements [dB]							
Mode	Data Rate [Mbps]							
	2	4	11	22				
802.11b	-8.66	-8.25	-6.18	-5.12				

### **Table 7-14**

802.11g (2.4GHz, SISO) Modulation Interference Factors<sup>1,2</sup>

	802.11g MIF Measurements [dB]									
Mode		Data Rate [Mbps]								
	6	9	12	18	24	36	48	54		
802.11g	-6.96	96 -6.20 -5.67 -4.95 -4.66 -4.56 -4.50 -4.47								

### **Table 7-15**

802.11g (2.4GHz, MIMO) Modulation Interference Factors<sup>1,2</sup>

802.11g MIF Measurements [dB]									
Mode		Data Rate [Mbps]							
	12	18	24	36	48	72	92	108	
802.11g	-3.62	-4.80	-4.50	-4.24	-4.33	-4.42	-4.35	-4.33	

### **Table 7-16**

802.11n (2.4GHz, SISO) Modulation Interference Factors<sup>1,2</sup>

<u> </u>											
	802.11n (2.4GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	1	2	3	4	5	6	7			
802.11n	-6.65	-5.52	-4.84	-4.60	-4.55	-4.41	-4.39	-3.95			

## **Table 7-17**

802.11n (2.4GHz, MIMO) Modulation Interference Factors<sup>1,2</sup>

	802.11n (2.4GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	1	2	3	4	5	6	7			
802.11n	-3.98	3.98 -5.34 -4.72 -3.86 -4.48 -4.32 -4.23 -3.87									

# **Table 7-18**

802.11ax (2.4GHz, SU, SISO) Modulation Interference Factors<sup>1,2</sup>

		20MHz 802.11ax (2.4GHz) MIF Measurements [dB]									
Mode		MCS Index									
	0	1	2	3	4	5	6	7	8	9	
802.11ax	-6.68	-6.83	-6.86	-6.66	-7.51	-6.98	-7.46	-7.40	-7.20	-6.74	

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 24 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 24 01 101

# **Table 7-19**802.11ax (2.4GHz. SU. MIMO) Modulation Interference Factors<sup>1,2</sup>

	602. Trax (2. Toriz, 60, Million) Modulation interference ractore											
	20MHz 802.11ax (2.4GHz) MIF Measurements [dB]											
Mode		MCS Index										
	0	1	2	3	4	5	6	7	8	9		
802.11ax	-7.35	-7.30	-6.53	-7.00	-7.71	-6.15	-6.53	-5.72	-5.69	-4.46		

### **Table 7-20**

802.11ax (2.4GHz, RU, SISO) Modulation Interference Factors<sup>1,2</sup>

		20MHz 80	2.11ax (2.4	4GHz) MIF	Measurem	ents [dB]					
Mode		RU Index (MCS Index 3) (GI 1.6us)									
0 8 37 40 53 54											
802.11ax	-14.52	-15.37	-14.38	-14.36	-15.37	-15.74	-15.35				

### **Table 7-21**

802.11ax (2.4GHz, RU, MIMO) Modulation Interference Factors<sup>1,2</sup>

		20MHz 80	2.11ax (2.4	4GHz) MIF	Measurem	ents [dB]					
Mode		RU Index (MCS Index 9) (GI 1.6us)									
	0 8 37 40 53 54 6										
802.11ax	-14.15	4.15									

### **Table 7-22**

802.11a (5GHz, 20MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

			802.1	1a MIF Mea	surements	s [dB]		
Mode	ode Data Rate [Mbps] 6 9 12 18 24 36 48 54							
802.11a	-7.25	-6.51	-6.00	-5.27	-5.05	-5.00	-4.93	-4.90

### **Table 7-23**

802.11a (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

002.116	3 (30112	, ZOIVII 12		IVIO) IVIO	dulation	IIIICIICI	crice i a	51013				
			802.1	1a MIF Mea	surement	s [dB]						
Mode	Data Rate [Mbps]											
12 18 24 36 48 72 92												
802.11a	-7.22	-6.46	-5.94	-5.23	-4.98	-4.94	-4.89	-4.88				

### **Table 7-24**

802.11n (5GHz, 20MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

20MHz BW 802.11n (5GHz) MIF Measurements [dB]											
Mode	MCS Index										
	0	1	2	3	4	5	6	7			
802.11n	-6.96	6.96 -5.86 -5.18 -4.95 -4.99 -4.85 -4.83 -4.61									

### **Table 7-25**

802.11n (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

		20MH	Iz BW 802.	.11n (5GHz	z) MIF Mea	surements	[dB]				
Mode	MCS Index										
	0 1 2 3 4 5 6										
802.11n	-6.89	6.89 -5.77 -5.16 -4.93 -4.99 -4.85 -4.81 -4.55									

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

FCC ID: A3LSMF916U	PCTEST: Float to be post of the second	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 25 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 25 of 101

802.11ac (5GHz, 20MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

	20MHz BW 802.11ac (5GHz) MIF Measurements [dB]									
Mode		MCS Index								
	0	1	2	3	4	5	6	7	8	
802.11ac	-6.98	-5.89	-5.16	-4.93	-4.97	-4.86	-4.84	-4.82	-4.21	

### **Table 7-27**

802.11ac (5GHz, 20MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

	20MHz BW 802.11ac (5GHz) MIF Measurements [dB]								
Mode		MCS Index							
	0 1 2 3 4 5 6 7 8								
802.11ac	-5.64	-4.81	-4.84	-4.72	-4.23	-3.77	-3.67	-3.58	-3.43

### **Table 7-28**

802.11ax (5GHz, 20MHz BW, SU, SISO) Modulation Interference Factors<sup>1,2</sup>

		0 <u>=: : : a, c</u>	(00:,		<u> </u>	, c.cc,	modulati	011 111101		. 40.010				
				20N	/IHz 802.11	ax (5GHz)	MIF Measu	urements [	dB]					
Mode		MCS Index												
	0	1	2	3	4	5	6	7	8	9	10	11		
802.11ax	-16.96	-17.04	-17.00	-16.69	-16.59	-16.50	-16.63	-16.52	-16.45	-16.34	-16.48	-16.58		

### **Table 7-29**

802.11ax (5GHz, 20MHz BW, SU, MIMO) Modulation Interference Factors<sup>1,2</sup>

				20N	/Hz 802.11	ax (5GHz)	MIF Measu	rements [	dB]					
Mode		MCS Index												
	0	1	2	3	4	5	6	7	8	9	10	11		
802.11ax	-15.60	-15.67	-15.91	-15.71	-15.73	-15.66	-15.67	-15.61	-15.67	-15.77	-15.57	-15.80		

### **Table 7-30**

802.11ax (5GHz, 20MHz BW, RU, SISO) Modulation Interference Factors<sup>1,2</sup>

20MHz 802.11ax (5GHz) MIF Measurements [dB]																			
Mode		RU Index (MCS Index 9) (GI 1.6us)									RU Index (MCS Index 9) (GI 1.6us)								
	0	8	37	40	53	54	61												
802.11ax	-14.89	-15.07	-15.49	-15.32	-16.00	-15.91	-15.71												

### **Table 7-31**

802.11ax (5GHz, 20MHz BW, RU, MIMO) Modulation Interference Factors<sup>1,2</sup>

		20MHz 802.11ax (5GHz) MIF Measurements [dB] RU Index (MCS Index 10) (GI 1.6us)											
Mode													
	0	8	37	40	53	54	61						
802.11ax	-13.45	3.45 -12.58 -13.08 -12.33 -15.72 -15.23 -16.35											

### **Table 7-32**

802.11n (5GHz, 40MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

	40MHz BW 802.11n (5GHz) MIF Measurements [dB]											
Mode		MCS Index										
	0	1	2	3	4	5	6	7				
802.11n	-5.47	-4.72	-4.66	-4.62	-3.50	-3.20	-2.98	-3.00				

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

FCC ID: A3LSMF916U	PCTEST:	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 26 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 26 of 101

802.11n (5GHz, 40MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

002.11	40MHz BW 802.11n (5GHz) MIF Measurements [dB]												
Mode		MCS Index											
	0	1	2	3	4	5	6	7					
802.11n	-5.39	39 -4.66 -4.69 -4.63 -3.50 -3.16 -2.99 -3.04											

### **Table 7-34**

802.11ac (5GHz, 40MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

		40MHz BW 802.11ac (5GHz) MIF Measurements [dB]													
Mode		MCS Index													
	0	0 1 2 3 4 5 6 7 8 9													
802.11ac	-5.46	.46 -4.73 -4.67 -4.60 -3.52 -3.19 -3.06 -3.02 N/A -2.89													

### **Table 7-35**

802.11ac (5GHz, 40MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

	40MHz BW 802.11ac (5GHz) MIF Measurements [dB]													
Mode		MCS Index												
	0	1	2	3	4	5	6	7	8	9				
802.11ac	-4.62	-4.59	-3.61	-3.35	-3.08	-2.95	-3.02	-2.97	N/A	-3.01				

### **Table 7-36**

802.11ax (5GHz, 40MHz BW, SU, SISO) Modulation Interference Factors<sup>1,2</sup>

	40MHz 802.11ax (5GHz) MIF Measurements [dB]												
Mode		MCS Index											
	0	1	2	3	4	5	6	7	8	9	10	11	
802.11ax	-15.90	-15.88	-16.13	-15.77	-15.78	-15.75	-15.69	-15.77	-15.67	-15.64	-15.69	-15.68	

### **Table 7-37**

802.11ax (5GHz, 40MHz BW, SU, MIMO) Modulation Interference Factors<sup>1,2</sup>

				40N	0MHz 802.11ax (5GHz) MIF Measurements [dB]								
Mode		MCS Index											
	0	1	2	3	4	5	6	7	8	9	10	11	
802.11ax	-15.16	16 -15.18 -15.14 -15.29 -15.00 -15.02 -15.04 -15.09 -14.97 -15.07 -15.00 -15.15											

### **Table 7-38**

802.11ax (5GHz, 40MHz BW, RU, SISO) Modulation Interference Factors<sup>1,2</sup>

	. 5.7. (5.6	· · · — , · · · · · ·	,		<i>(</i> )								
		40MHz 802.11ax (5GHz) MIF Measurements [dB]											
Mode		RU Index (MCS Index 9 ) (GI 1.6us)											
	0	17	37	44	53	56	61	62	65				
802.11ax	-14.78	-14.43	-15.10	-15.37	-15.35	-15.36	-15.15	-14.98	-15.17				

### **Table 7-39**

802.11ax (5GHz, 40MHz BW, RU, MIMO) Modulation Interference Factors<sup>1,2</sup>

		40MHz 802.11ax (5GHz) MIF Measurements [dB]												
Mode		RU Index (MCS Index 8) (GI 1.6us)												
	0	17	37	44	53	56	61	62	65					
802.11ax	-13.10	-13.18	-15.99	-16.04	-15.88	-16.41	-17.59	-16.94	-18.59					

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

FCC ID: A3LSMF916U	PCTEST.  Float to be goth of the senses.	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 27 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 27 of 101

802.11ac (5GHz, 80MHz BW, SISO) Modulation Interference Factors<sup>1,2</sup>

	80MHz BW 802.11ac (5GHz) MIF Measurements [dB]													
Mode		MCS Index												
	0	1	2	3	4	5	6	7	8	9				
802.11ac	-4.93	-3.88 -3.06 -2.76 -2.44 -2.41 -2.38 -2.35 -2.33 -2.25												

### **Table 7-41**

802.11ac (5GHz, 80MHz BW, MIMO) Modulation Interference Factors<sup>1,2</sup>

	80MHz BW 802.11ac (5GHz) MIF Measurements [dB]													
Mode		MCS Index												
	0	1	2	3	4	5	6	7	8	9				
802.11ac	-4.11	1 -2.86 -2.68 -2.63 -2.49 -2.49 -2.52 -2.57 -2.56 -2.54												

### **Table 7-42**

802.11ax (5GHz, 80MHz BW, SU, SISO) Modulation Interference Factors<sup>1,2</sup>

		OZ. I TAX	(00112,	OUIVII IZ	<u> </u>	, cicc,	Modelati		0101100	actore					
		80MHz 802.11ax (5GHz) MIF Measurements [dB]													
Mode		MCS Index													
	0	1	2	3	4	5	6	7	8	9	10	11			
802.11ax	-16.29	-16.25	-16.14	-16.23	-16.09	-16.16	-16.18	-15.98	-16.16	-15.99	-16.14	-16.22			

### **Table 7-43**

802.11ax (5GHz, 80MHz BW, SU, MIMO) Modulation Interference Factors<sup>1,2</sup>

			·	80N	/Hz 802.11	ax (5GHz)	MIF Measu	rements [	dB]			
Mode	MCS Index											
	0	1	2	3	4	5	6	7	8	9	10	11
802.11ax	-15.55	-15.67	-15.63	-15.64	-15.62	-15.74	-15.76	-15.48	-15.69	-15.83	-15.71	-15.72

### **Table 7-44**

802.11ax (5GHz, 80MHz BW, RU, SISO) Modulation Interference Factors<sup>1,2</sup>

				80MHz 8	02.11ax (5	GHz) MIF I	Measureme	ents [dB]				
Mode		RU Index (MCS Index 7) (GI 1.6us)										
	0	36	37	52	53	60	61	64	65	66	67	
802.11ax	-15.18	-15.41	-15.82	-14.89	-15.25	-15.19	-15.93	-15.97	-15.57	-15.44	-14.98	

### **Table 7-45**

802.11ax (5GHz, 80MHz BW, RU, MIMO) Modulation Interference Factors<sup>1,2</sup>

				80MHz 8	02.11ax (5	GHz) MIF I	Measureme	ents [dB]						
Mode		RU Index (MCS Index 7) (GI 1.6us)												
	0	36	37	52	53	60	61	64	65	66	67			
802.11ax	-13.88													

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 28 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 20 01 101

<sup>&</sup>lt;sup>2</sup> Note: WIFI MIF values were found to be independent of the transmit channel.

Table 7-46
Simultaneous 2.4GHz and 5GHz WIFI Modulation Interference Factors<sup>1,2,3</sup>

#	5 GH	z WIFI Bm]	2.4 GH	Iz WIFI	Measured MIF (dB)
Tx	Ant1	Ant2	Ant1	Ant2	` ′
2	х	-	-	х	-8.64
2	•	x	х	1	-10.51
2	х	1	х	1	-8.93
2	-	x	-	х	-8.65
3	х	х	х	1	-15.62
3	х	х	•	х	-15.61
3	x	-	х	x	-4.08
3	-	х	х	х	-4.92
4	х	х	х	х	-15.62

<sup>&</sup>lt;sup>1</sup> Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

FCC ID: A3LSMF916U	POTEST: Road to las port of the second	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 20 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 29 of 101

<sup>&</sup>lt;sup>2</sup> Note: WLAN MIF values were found to be independent of the transmit channel.

<sup>&</sup>lt;sup>3</sup> Note: The configuration for each scenario (e.g. bandwidth, data rate, etc.) was determined using the worst-case configuration from SISO and MIMO MIF measurements.

# 8. RF CONDUCTED POWER MEASUREMENTS

# I. Procedures Used to Establish RF Signal for HAC Testing

The handset was configured to transmit the required air interface in a shielded chamber. Measurements were taken with a fully charged battery.

### II. HAC Measurement Conditions

## **Output Power Verification**

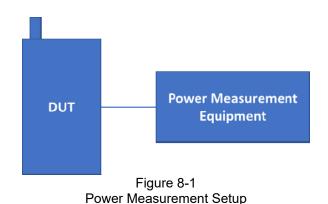
Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces for which full testing scans are required. Modes which are exempted from full testing according to Section 9 of this report have only their conducted power targets listed below, not measured values. See Table 8-1 for air interface specific settings of transmit power parameters. See Table 9-1 for more information regarding which modes required full testing and had conducted power measurements taken.

Table 8-1
Power Control Parameters and Settings by Air Interface

Air Interface:	Parameter Name:	Parameter Set To:
CDMA	Power Control Bits	"All Up"
GSM	PCL	GSM850: "5"; GSM1900: "0"
UMTS	TPC	"All 1's"
LTE	TPC	"Max Power"
NR	PLS	Mfr Specified
WIFI	PLS	Mfr Specified

# III. Setup Used to Measure RF Conducted Powers

The general setup for conducted power is shown in Figure 8-1 below. The power measurement equipment could be a base station simulator, signal analyzer, or power meter depending on the applicable air interface.



FCC ID: A3LSMF916U	Post ST.  Read to be post of the second HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 20 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 30 of 101

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# **IV. CDMA Conducted Powers**

Table 8-2
CDMA Conducted Powers – Ant A

Band	Channel	Rule Part	Frequency	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO75 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]	1x EvDO Rev. A [dBm]
	F-RC		MHz	RC1	RC3	RC4	RC1	RC3	RC11	RC2	RC5	RC1	RC3	RC4	(RETAP)
Cellular	564	90S	820.1	25.13	25.11	25.11	25.09	25.11	25.24	25.10	25.09	25.12	25.08	25.13	25.18
	1013	22H	824.7	25.14	25.12	25.12	25.13	25.13	25.29	25.13	25.12	25.19	25.17	25.15	25.22
Cellular	384	22H	836.52	25.11	25.11	25.12	25.13	25.12	25.27	25.13	25.11	25.16	25.18	25.22	25.17
	777	22H	848.31	25.05	25.03	25.02	25.05	25.04	25.20	25.06	25.05	25.13	25.10	25.12	25.07
	25	24E	1851.25	22.81	22.82	22.82	22.82	22.82	22.97	22.81	22.83	22.81	22.81	22.80	23.04
PCS	600	24E	1880	22.88	22.86	22.87	22.87	22.87	23.01	22.88	22.88	22.87	22.89	22.89	23.19
	1175	24E	1908.75	22.92	22.91	22.90	22.92	22.91	23.17	22.91	22.90	22.92	22.92	22.92	23.18

Table 8-3
CDMA Conducted Powers – Ant B

Band	Channel	Rule Part	Frequency	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO75 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]	1x EvDO Rev. A [dBm]
	F-RC		MHz	RC1	RC3	RC4	RC1	RC3	RC11	RC2	RC5	RC1	RC3	RC4	(RETAP)
	1013	22H	824.7	23.53	23.52	23.51	23.52	23.53	23.49	23.52	23.53	23.52	23.54	23.51	23.57
Cellular	384	22H	836.52	23.46	23.47	23.46	23.48	23.45	23.44	23.45	23.45	23.45	23.45	23.45	23.54
	777	22H	848.31	23.31	23.33	23.31	23.33	23.32	23.30	23.32	23.32	23.30	23.29	23.31	23.34

# V. GSM Conducted Powers

Table 8-4
GSM Conducted Powers – Ant A

Ooly Colladeled Lowers - All A				
Band	Channel	GSM [dBm] CS (1 Slot)	EDGE [dBm] 1 Tx Slot	
	128	33.18	26.46	
GSM 850	190	33.05	26.61	
	251	33.14	26.63	
	512	29.38	25.79	
GSM 1900	661	28.89	25.92	
	810	29.20	26.12	

Table 8-5
GSM Conducted Powers – Ant B

Band	Channel	GSM [dBm] CS (1 Slot)	EDGE [dBm] 1 Tx Slot
	128	31.42	25.80
GSM 850	190	31.18	25.90
	251	31.41	25.65

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 21 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 31 of 101

# **VI. UMTS Target Powers**

Table 8-6
UMTS Conducted Power Targets

		Modulated Average (dBm)			Bm)
Mode / Band		3GPP	3GPP	3GPP	3GPP
		WCDMA	HSDPA	HSUPA	DC-HSDPA
UMTS Band 5 (850 MHz)	Maximum	25.8	24.8	24.8	24.8
UIVITS BATTU 5 (850 IVITIZ)	Nominal	24.8	23.8	23.8	23.8
UMTS Band 4 (1750 MHz)	Maximum	25.5	24.5	24.5	24.5
OIVITS BAITU 4 (1750 IVITIZ)	Nominal	24.5	23.5	23.5	23.5
UMTS Band 2 (1900 MHz)	Maximum	24.5	23.5	23.5	23.5
OIVITS DATIU 2 (1900 IVITIZ)	Nominal	23.5	22.5	22.5	22.5

# VII. LTE FDD Target Powers

Table 8-7
LTE FDD Conducted Power Targets – Ant A

		Modulated
Mode / Band		Average Output
,		Power (in dBm)
	Max allowed	25.8
LTE FDD Band 71	Nominal	24.8
	Max allowed	25.8
LTE FDD Band 12	Nominal	24.8
LTE 500 0	Max allowed	25.8
LTE FDD Band 13	Nominal	24.8
LTC CDD David 14	Max allowed	25.8
LTE FDD Band 14	Nominal	24.8
LTE CDD Band F	Max allowed	25.8
LTE FDD Band 5	Nominal	24.8
LTE FDD Band 26	Max allowed	25.8
LTE FDD Ballu 20	Nominal	24.8
LTE FDD Band 4	Max allowed	25.0
LTE FDD Ballu 4	Nominal	24.0
LTE FDD Band 66	Max allowed	25.0
ETET DD Baild 00	Nominal	24.0
LTE FDD Band 2	Max allowed	25.5
ETET DD Band 2	Nominal	24.5
LTE FDD Band 25	Max allowed	25.5
ETET DD Band 25	Nominal	24.5
LTE FDD Band 30	Max allowed	25.0
LILI DD Dana 30	Nominal	24.0
LTE FDD Band 7	Max allowed	25.0
LILIDD Ballu /	Nominal	24.0

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 32 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		raye 32 01 101

Table 8-8
LTE FDD Conducted Power Targets – Ant B

		Modulated	
Mode / Band		Average Output	
		Power (in dBm)	
LTE FDD Band 71	Max allowed	23.8	
	Nominal	22.8	
LTE FDD Band 12	Max allowed	23.8	
	Nominal	22.8	

Table 8-9
LTE FDD Uplink Carrier Aggregation Conducted Power Targets

	<u> </u>	
		Modulated
Mode / Band		Average Output
		Power (in dBm)
LTE FDD Band 5	Max allowed	25.8
	Nominal	24.8
LTE FDD Band 66	Max allowed	25.0
LIE FDD Band 66	Nominal	24.0

# **VIII.** LTE TDD Target Powers

Table 8-10 LTE TDD Conducted Power Targets<sup>1</sup>

LIL IDD Conducted Fower rangets			
		Modulated	
Mode / Band		Average Output	
		Power (in dBm)	
LTE TDD Band 48	Max allowed	25.0	
	Nominal	24.0	
LTE TDD Band 41 (DC2)	Max allowed	25.0	
LTE TDD Band 41 (PC3)	Nominal	24.0	
LTE TDD Band 41 (PC2)	Max allowed	28.0	
LIE IDD Band 41 (PC2)	Nominal	27.0	
LTE TDD Band 38	Max allowed	25.0	
LIE IDD Ballu 38	Nominal	24.0	

<sup>1</sup>Note: Conducted power levels were additionally measured to verify operating power levels of configurations used in Section 11

Table 8-11
LTE TDD Uplink Carrier Aggregation Conducted Power Targets

		Modulated
Mode / Band		Average Output
		Power (in dBm)
LTE TDD Band 48	Max allowed	25.0
	Nominal	24.0
LTE TDD Band 41 (PC3)	Max allowed	25.0
LTE TOO Ballu 41 (PCS)	Nominal	24.0
LTE TDD Band 41 (PC2)	Max allowed	28.0
LTE TOO Balla 41 (PC2)	Nominal	27.0

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 33 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 33 01 101

# **IX. NR FDD Target Powers**

Table 8-12 NR FDD Conducted Power Targets

Mode / Band		Modulated Average Output Power (in dBm)
NR FDD Band 71	Max allowed	25.5
INN FDD Ballu 71	Nominal	24.5
NR FDD Band 5	Max allowed	25.5
INK FDD Ballu 3	Nominal	24.5
NR FDD Band 2	Max allowed	24.5
INK FDD Ballu 2	Nominal	23.5
ND EDD Band 66	Max allowed	24.5
NR FDD Band 66	Nominal	23.5
NR FDD Band 25	Max allowed	24.5
INK FUU Band 25	Nominal	23.5

# X. NR TDD Conducted Powers

# a. NR n41

Table 8-13
NR n41 (2593.0MHz) Conducted Powers – 100MHz Bandwidth

			Channel		
Modulation	RB Size	RB Offset	518598 (2592.99 MHz)	MPR Allowed per 3GPP	MPR [dB]
Modulation	KB Size		Conducted Power [dBm]	[dB]	[ub]
	1	1	24.12		0.0
	1	137	24.04	0	0.0
DFT-s-OFDM	1	271	24.03		0.0
π/2 BPSK	135	0	23.53	0-0.5	0.5
WZ BI SK	135	69	23.83	0	0.0
	135	138	23.47	0-0.5	0.5
	270	0	23.46	0-0.5	0.5
	1	1	24.16		0.0
	1	137	24.05	0	0.0
DFT-s-OFDM	1	271	24.08		0.0
QPSK	135	0	22.99	0-1	1.0
QFSK	135	69	23.87	0	0.0
	135	138	22.81	0-1	1.0
	270	0	23.01	0-1	1.0
DFT-s-OFDM 16QAM	1	1	23.33	0-1	1.0
CP-OFDM QPSK	1	1	22.79	0-1.5	1.5

FCC ID: A3LSMF916U	Post is to post at the second HA	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 24 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 34 of 101

Table 8-14
NR n41 (2593.0MHz) Conducted Powers – 90MHz Bandwidth

		Cha	nnel			
Modulation	RB Size	RB Size RB Offset	508200 (2541 MHz)	528996 (2644.98 MHz)	MPR Allowed per 3GPP	MPR [dB]
			Conducted	Power [dBm]	[dB]	
	1	1	24.11	23.69		0.0
	1	123	23.72	24.12	0	0.0
DFT-s-OFDM	1	243	23.80	23.65		0.0
π/2 BPSK	120	0	23.46	23.29	0-0.5	0.5
WZ BI SK	120	63	23.75	24.06	0	0.0
	120	125	23.39	23.25	0-0.5	0.5
	243	0	23.36	23.57	0-0.5	0.5
	1	1	24.06	23.58		0.0
	1	123	23.88	24.23	0	0.0
DFT-s-OFDM	1	243	23.90	23.73		0.0
OPSK	120	0	22.93	23.36	0-1	1.0
QFSIX	120	63	23.79	24.02	0	0.0
	120	125	22.82	23.15	0-1	1.0
	243	0	22.87	23.08	U- I	1.0
DFT-s-OFDM 16QAM	1	1	23.15	22.68	0-1	1.0
CP-OFDM QPSK	1	1	22.57	22.14	0-1.5	1.5

Table 8-15
NR n41 (2593.0MHz) Conducted Powers – 80MHz Bandwidth

			Cha	nnel		
Modulation	RB Size	RB Offset	507204 (2536.02 MHz)	529998 (2649.99 MHz)	MPR Allowed per 3GPP	MPR [dB]
			Conducted	Power [dBm]	[dB]	
	1	1	23.82	23.43		0.0
	1	109	23.71	24.19	0	0.0
DFT-s-OFDM	1	215	23.85	23.69		0.0
π/2 BPSK	108	0	23.39	23.72	0-0.5	0.5
MZ BF SK	108	55	23.68	24.04	0	0.0
	108	109	23.35	23.38	0-0.5	0.5
	216	0	23.48	23.29	0-0.5	0.5
	1	1	23.79	23.33		0.0
	1	109	23.77	24.08	0	0.0
DFT-s-OFDM	1	215	23.86	23.47		0.0
QPSK	108	0	22.84	23.23	0-1	1.0
QF SIX	108	55	23.78	24.12	0	0.0
	108	109	22.81	23.33	0-1	1.0
	216	0	22.78	23.17	0-1	1.0
DFT-s-OFDM 16QAM	1	1	22.68	22.37	0-1	1.0
CP-OFDM QPSK	1	1	22.61	22.23	0-1.5	1.5

FCC ID: A3LSMF916U	POTEST: Proad to be part of the second	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 25 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 35 of 101

Table 8-16
NR n41 (2593.0MHz) Conducted Powers – 60MHz Bandwidth

			, conducted	1 0We13 - 00	= = aa		
				Channel			
Modulation	RB Size	RB Offset	505200 (2526 MHz)	518598 (2592.99 MHz)	531996 (2659.98 MHz)	MPR Allowed per 3GPP	MPR [dB]
			Cor	[dB]			
	1	1	23.81	24.23	23.75		0.0
	1	81	23.79	24.34	24.29	0	0.0
DFT-s-OFDM	1	160	23.97	24.20	23.91		0.0
DF1-S-OFDM π/2 BPSK	81	0	23.69	23.66	23.64	0-0.5	0.5
	81	41	23.75	24.08	24.07	0	0.0
	81	81	23.42	23.41	23.66	0-0.5	0.5
	162	0	23.19	23.14	22.92		0.5
	1	1	24.13	23.84	23.62	0	0.0
	1	81	23.84	24.17	23.96		0.0
DET - OFDM	1	160	24.18	23.94	23.77		0.0
DFT-s-OFDM QPSK	81	0	23.03	23.34	23.31	0-1	1.0
QFSIX	81	41	23.69	24.06	24.07	0	0.0
	81	81	22.82	23.35	23.40	0-1	1.0
	162	0	22.87	23.10	23.33	] "-1	1.0
DFT-s-OFDM 16QAM	1	1	22.81	23.36	22.81	0-1	1.0
CP-OFDM QPSK	1	1	21.93	22.90	22.46	0-1.5	1.5

Table 8-17
NR n41 (2593.0MHz) Conducted Powers – 50MHz Bandwidth

			Channel				
Modulation	RB Size	RB Offset	504204 (2521.02 MHz)	518598 (2592.99 MHz)	532998 (2664.99 MHz)	MPR Allowed per 3GPP	MPR [dB]
			Cor	Conducted Power [dBm]			
	1	1	23.96	24.19	24.22		0.0
	1	67	24.11	24.36	24.31	0	0.0
DFT-s-OFDM	1	131	24.02	23.88	24.05		0.0
π/2 BPSK	64	0	23.61	23.70	23.82	0-0.5	0.5
WZ DF SK	64	35	23.85	24.18	24.26	0	0.0
	64	69	23.44	23.48	23.69	0-0.5	0.5
	128	0	22.72	23.39	23.07		0.5
	1	1	24.12	24.04	23.73	0	0.0
	1	67	23.83	24.10	24.26		0.0
DFT-s-OFDM	1	131	23.81	24.12	23.80		0.0
QPSK	64	0	22.94	23.26	23.42	0-1	1.0
QFSK	64	35	23.84	24.17	24.25	0	0.0
	64	69	22.82	23.29	23.54	0-1	1.0
	128	0	22.87	23.38	23.42	U- I	1.0
DFT-s-OFDM 16QAM	1	1	23.05	23.54	22.99	0-1	1.0
CP-OFDM QPSK	1	1	22.63	22.84	22.62	0-1.5	1.5

FCC ID: A3LSMF916U	PCTEST HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 36 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 30 01 101

**Table 8-18** NR n41 (2593.0MHz) Conducted Powers - 40MHz Bandwidth

		,		Cha	nnel	Janawiath		
Modulation	RB Size	RB Offset	503202 (2516.01 MHz)	513468 (2567.34 MHz)	523734 (2618.67 MHz)	534000 (2670 MHz)	MPR Allowed per 3GPP	MPR Allowed per 3GPP
				Conducted	Power [dBm]		[dB]	[dB]
	1	1	23.93	24.36	24.12	24.47		0.0
	1	53	24.26	24.34	24.44	24.56	0	0.0
DFT-s-OFDM	1	104	24.38	24.28	24.38	23.94		0.0
π/2 BPSK	50	0	23.64	24.23	24.07	24.12	0-0.5	0.5
WZ DI SK	50	28	24.07	24.39	24.30	24.48	0	0.0
	50	56	23.68	24.05	24.02	24.12	0-0.5	0.5
	100	0	23.66	23.39	23.73	23.35	0-0.5	0.5
	1	1	23.77	24.10	24.59	24.50		0.0
	1	53	24.32	24.16	24.42	24.46	0	0.0
DFT-s-OFDM	1	104	24.25	23.92	24.38	24.21		0.0
QPSK	50	0	23.29	23.69	23.58	23.68	0-1	1.0
Qi Sit	50	28	24.18	24.22	24.35	24.31	0	0.0
	50	56	23.11	23.49	23.56	23.62	0-1	1.0
	100	0	23.14	23.56	23.52	23.84	0-1	1.0
DFT-s-OFDM 16QAM	1	1	22.98	23.87	23.25	23.42	0-1	1.0
CP-OFDM QPSK	1	1	22.46	23.14	22.87	23.17	0-1.5	1.5

**Table 8-19** NR n41 (2593.0MHz) Conducted Powers – 20MHz Bandwidth

		•	·		Channel				
Modulation	RB Size	RB Offset	501204 (2506.02 MHz)	509898 (2549.49 MHz)	518598 (2592.99 MHz)	527298 (2636.49 MHz)	535998 (2679.99 MHz)	MPR Allowed per 3GPP	MPR [dB]
				Cor	nducted Power [d	Bm]		[dB]	
	1	1	24.12	24.18	24.12	24.22	24.29		0.0
	1	26	24.17	24.09	24.31	24.24	23.91	0	0.0
DFT-s-OFDM	1	49	24.01	24.11	23.97	24.09	23.96		0.0
π/2 BPSK	25	0	23.62	23.44	23.62	23.65	24.11	0-0.5	0.5
WZ DI SK	25	13	24.06	23.99	24.07	24.08	24.32	0	0.0
	25	26	23.72	23.48	23.72	23.63	24.12	0-0.5	0.5
	50	0	23.69	23.53	23.76	23.67	23.93	0-0.5	0.5
	1	1	23.97	23.87	24.17	24.04	24.34		0.0
	1	26	24.08	23.94	24.02	24.19	24.23	0	0.0
DFT-s-OFDM	1	49	23.89	23.92	24.06	24.12	23.87		0.0
QPSK	25	0	23.18	23.01	23.31	23.30	23.49	0-1	1.0
Qron	25	13	24.06	24.03	24.07	24.09	24.35	0	0.0
	25	26	22.96	22.85	23.29	23.24	23.48	0-1	1.0
	50	0	23.07	22.96	23.24	23.25	23.53	0-1	1.0
DFT-s-OFDM 16QAM	1	1	23.22	23.15	23.42	23.31	23.32	0-1	1.0
CP-OFDM QPSK	1	1	22.58	22.49	22.82	22.62	23.11	0-1.5	1.5

FCC ID: A3LSMF916U	PCTEST:	IAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 37 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		raye 3/ 01 101

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## XI. WIFI Target Powers (SISO/MIMO)

**Table 8-20** IEEE 2.4GHz 802.11b/g/n/ax(SU) Reduced Average RF Power Targets<sup>1</sup>

						<u> </u>		<u> </u>		<del></del>	<del> </del>	• • • • •	· · · · · ·	. w. g v			
									IEEE 802.1	1 (in dBm)							
Mode	Band				SI	so							MII	МО			
		b	)	g	9	r	1	ax (	SU)	(CDD +	STBC)	(CDD +	STBC)	(CDD+STE		ax ( (CDD+ST	
	mum / al Power	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.
2.4 GHz WIFI	2.45 GHz	17.0	16.0	17.0	16.0	17 ch.1: 16.5 ch.11: 16.0	16 ch.1: 15.5 ch.11: 15.0	17 ch.11: 16.0	16 ch.11: 15.0	20.0	19.0	20.0	19.0	20 ch.1: 19.5 ch.11: 19.0	19 ch.1: 18.5 ch.11: 18.0	20 ch.11: 19.0	19 ch.11: 18.0

**Table 8-21** IEEE 5GHz 802.11a/n/ac/ax(SU) Reduced Average RF Power Targets<sup>1</sup>

			_ 50	112 002	. ı ıaı	macra	<b>X</b> ( <b>O</b> C	,		1 (in dBm)	ge iv	r Powe	51 I C	ai gets			
Mode	Band				SIS	60				, ,			MII	MO			
Wiede	Bana	а		n		ac		ax (Sl	J)	a (CDD + ST	BC)	n (CDD+STBC,	SDM)	ac (CDD+STBC,	SDM)	ax (SI (CDD+STBC	
	ı / Nominal wer	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.
	5200 MHz	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0	17.0	16.0	17.0	16.0	17.0	16.0	17.0	16.0
5 GHz WIFI	5300 MHz	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0	17.0	16.0	17.0	16.0	17.0	16.0	17.0	16.0
(20MHz BW)	5500 MHz	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0	17.0	16.0	17.0	16.0	17.0	16.0	17.0	16.0
,	5800 MHz	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0	17.0	16.0	17.0	16.0	17.0	16.0	17.0	16.0
	5200 MHz			14.0	13.0	14.0	13.0	14.0	13.0			17.0	16.0	17.0	16.0	17.0	16.0
5 GHz WIFI	5300 MHz			14.0	13.0	14.0	13.0	14.0	13.0			17.0	16.0	17.0	16.0	17.0	16.0
(40MHz BW)	5500 MHz			14.0	13.0	14.0	13.0	14.0	13.0			17.0	16.0	17.0	16.0	17.0	16.0
,	5800 MHz			14.0	13.0	14.0	13.0	14.0	13.0			17.0	16.0	17.0	16.0	17.0	16.0
	5200 MHz					14.0	13.0	14.0	13.0					17.0	16.0	17.0	16.0
5 GHz WIFI	5300 MHz					14.0	13.0	14.0	13.0					17.0	16.0	17.0	16.0
(80MHz BW)	5500 MHz					14.0	13.0	14.0	13.0					17.0	16.0	17.0	16.0
	5800 MHz					14.0	13.0	14.0	13.0					17.0	16.0	17.0	16.0

#### WIFI Target Powers for IEEE 802.11ax RU (SISO/MIMO) XII.

**Table 8-22** IEEE 802.11ax (RU) Reduced Average RF Power Targets<sup>1,2</sup>

		1222.1	iax (ito) ito	duced Ave	iage iti i o	wei laigets	•	
Tones		SISO (ANT	1/2) /in dBm			MIMO (AL	L) /in dBm	
Tones	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz
26T	12	8	8	8	15	11	11	11
52T	12	10	9	9	15	13	12	12
106T	12	10	10	10	15	13	13	13
242T	12	10	10	10	15	13	13	13
484T			10	10			13	13
996T				10				13

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

<sup>&</sup>lt;sup>2</sup> Max allowed power = Target Power + 1.0dB

FCC ID: A3LSMF916U	POTEST Pour to be part of the second	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 29 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 38 of 101

#### XIII. WIFI Target Powers for Operations with Simultaneous 2.4GHz and 5GHz

**Table 8-23** IEEE 2.4GHz 802.11b/g/n/ax(SU) Reduced Average RF Power Targets<sup>1</sup>

				2.7011	2 002	. i ib/g	IIIIAA	(OO) 1	Cauc	cu Av	crage	171 1 1	34461	ı aı gc	LO		
									IEEE 802.1	1 (in dBm)							
Mode	Band				SI	so							MII	МО			
		t	)	g n ax (SU)					SU)	b g n (CDD + STBC) (CDD + STBC) (CDD+STBC, SDM)					ax ( (CDD+STE		
	mum / al Power	Max	Max Nom. Max Nom. Max Nom. Ma					Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.
2.4 GHz	2.45 GHz	13.0	12.0	13.0	12.0	13.0	12.0	13.0	12.0	16.0	15.0	16.0	15.0	16.0	15.0	16.0	15.0

**Table 8-24** IFFF 802 11a/n/ac/ax(SU) Reduced Average RF Power Targets<sup>1</sup>

		II		802.11	a/n/a	ic/ax(5	U) R	eauce	J AV	erage	Kr i	ower l	arg	ets			
								IEEE	802.1	1 (in dBm)							
Mode	Band				SIS	80							MII	МО			
Wodo	Bana	а		n	n ac ax (S		ax (Sl	J)	a (CDD + ST	ГВС)	n (CDD+STBC	SDM)	ac (CDD+STBC,	SDM)	ax (SU) (CDD+STBC,		
	/ Nominal wer	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.	Max	Nom.
	5200 MHz	11.0	10.0	11.0	10.0	11.0	10.0	11.0	10.0	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0
5 GHz WIFI	5300 MHz	11.0	10.0	11.0	10.0	11.0	10.0	11.0	10.0	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0
(20MHz BW)	5500 MHz	11.0	10.0	11.0	10.0	11.0	10.0	11.0	10.0	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0
,	5800 MHz	11.0	10.0	11.0	10.0	11.0	10.0	11.0	10.0	14.0	13.0	14.0	13.0	14.0	13.0	14.0	13.0
	5200 MHz			11.0	10.0	11.0	10.0	11.0	10.0			14.0	13.0	14.0	13.0	14.0	13.0
5 GHz WIFI	5300 MHz			11.0	10.0	11.0	10.0	11.0	10.0			14.0	13.0	14.0	13.0	14.0	13.0
(40MHz BW)	5500 MHz			11.0	10.0	11.0	10.0	11.0	10.0			14.0	13.0	14.0	13.0	14.0	13.0
,	5800 MHz			11.0	10.0	11.0	10.0	11.0	10.0			14.0	13.0	14.0	13.0	14.0	13.0
	5200 MHz					11.0	10.0	11.0	10.0					14.0	13.0	14.0	13.0
5 GHz WIFI	5300 MHz					11.0	10.0	11.0	10.0					14.0	13.0	14.0	13.0
(80MHz BW)	5500 MHz					11.0	10.0	11.0	10.0					14.0	13.0	14.0	13.0
,	5800 MHz					11.0	10.0	11.0	10.0					14.0	13.0	14.0	13.0

**Table 8-25** IEEE 802.11ax (RU) Reduced Average RF Power Targets<sup>1,2</sup>

		SISO (ANT					L) /in dBm	
Tones	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz
26T	12	8	8	8	15	11	11	11
52T	12	10	9	9	15	13	12	12
106T	12	10	10	10	15	13	13	13
242T	12	10	10	10	15	13	13	13
484T			10	10			13	13
996T				10				13

<sup>&</sup>lt;sup>1</sup> Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 39 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 39 01 101

<sup>&</sup>lt;sup>2</sup> Max allowed power = Target Power + 1.0dB

### 9. JUSTIFICATION OF HELD TO EAR MODES TESTED

### I. Analysis of RF Air Interface Technologies

An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst-case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes. RF air interface technologies exempted from testing in this manner are automatically assigned an M4 rating to be used in determining the overall rating for the WD.

The worst-case MIF plus the worst-case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

#### II. Individual Mode Evaluations

Table 9-1

Max Power + MIF calculations for Low Power Exemptions

Air Interface	Maximum Average Power	Worst Case MIF	Total (Power +	C63.19 Testing
	(dBm)	(dB)	MIF, dB)	Required
CDMA - Full Frame Rate	25.18	-19.71	5.47	No
CDMA - 1/8 <sup>th</sup> Frame Rate	16.16*	3.04	19.20	Yes
CDMA - EvDO	25.22	-19.04	6.18	No
GSM - GSM850	23.99*	3.53	27.52	Yes
GSM - GSM1900	20.19*	3.51	23.70	Yes
GSM - EDGE850	17.44*	3.68	21.12	Yes**
GSM - EDGE1900	16.93*	3.52	20.45	Yes**
UMTS - RMC	25.80	-24.27	1.53	No
UMTS - AMR	25.80	-13.48	12.32	No
UMTS - HSPA	24.80	-23.00	1.80	No
LTE FDD	25.80	-9.12	16.68	No
LTE FDD - Uplink Carrier Aggregation	25.80	-9.38	16.42	No
LTE TDD - Band 41 (PC3)	14.29*	3.69	17.98	Yes
LTE TDD - Band 41 (PC2)	20.31*	1.57	21.88	Yes
LTE TDD - Band 48	14.29*	3.58	17.87	Yes
LTE TDD - Uplink Carrier Aggregation	20.31*	1.43	21.74	Yes***
NR FDD	25.50	-10.06	15.44	No
NR TDD	18.57*	1.34	19.91	Yes
WIFI - 2.4GHz	20.00	-3.62	16.38	No
WIFI - 5GHz	17.00	-2.25	14.75	No
Simultaneous 2.4GHz and 5GHz WIFI Operations	17.13****	-4.08	13.05	No

FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 40 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 40 of 101

- \* Note: ANSI C63.19-2011 Sec. 4.4 Footnote 20 indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.
- \*\* Note: EDGE data modes were considered but not tested as GSM voice modes were found to be the worst-case modes for the GSM air interface.
- \*\*\* Note: LTE TDD Uplink Carrier Aggregation data modes were considered but not tested as LTE standalone modes were found to be the worst-case modes for the LTE air interface.
- \*\*\*\* Note: This value is calculated as the linear sum of the worst-case power for each band and antenna combination while in simultaneous 2.4GHz and 5GHz operation. This calculation is conservative and for use in this investigation only.

#### **III. Low-Power Exemption Conclusions**

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for GSM/CDMA 1/8<sup>th</sup> Frame Rate voice modes as well as LTE TDD (Power Class 3 and Power Class 2) and NR TDD data modes. All other air interfaces are exempt.

FCC ID: A3LSMF916U	Post ST.  Read to be post of the second HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 41 of 101
1M2005200087-19-R1.A3L 07/13/2020 - 08/02/2020		Portable Handset		Page 41 of 101

#### 10. LTE TDD UPLINK-DOWNLINK CONFIGURATION

### I. Uplink-Downlink Configuration Additional Testing

Additional testing was performed on each supported power class for LTE TDD to determine the worst-case Uplink-Downlink configuration for RFE testing.

Per 3GPP TS 36.211, the total frame length for each TDD radio frame of length  $T_f$  = 307200 ·  $T_s$  = 10 ms, where  $T_s$  is a number of time units equal to 1/(15000 x 2048) seconds. Additionally, each radio frame consists of 10 subframes, each of length  $30720 \cdot T_s$  = 1 ms, and subframes can be designated as uplink (U), downlink (D), or special subframe (S), depending on the Uplink-Downlink configuration as indicated in Table 4.2-2 of 3GPP TS 36.211. In the transmission duty factor calculation, the special subframe configuration with the shortest UpPTS duration within the special subframe is used and will be applied for measurement. From 3GPP TS 36.211 Table 4.2-1, the shortest UpPTS is 2192 · Ts which occurs in the normal cyclic prefix and special subframe configuration 4.

See table below outlining the calculated transmission duty cycles for each Uplink-Downlink configuration:

Table 10-1
Uplink-Downlink Configurations for Type 2 Frame Structures

Uplink-downlink configuration	Downlink-to-Uplink Switch-point periodicity				Su	bfram	e numb	oer				Calculated Transmission
configuration	Switch-point periodicity	0	1	2	3	4	5	6	7	8	9	Duty Cycle (%)
0	5 ms	D	S	U	U	U	D	S	U	U	U	61.4%
1	5 ms	D	S	U	U	D	D	S	U	U	D	41.4%
2	5 ms	D	S	U	D	D	D	S	U	D	D	21.4%
3	10 ms	D	S	U	U	U	D	D	D	D	D	30.7%
4	10 ms	D	S	U	U	D	D	D	D	D	D	20.7%
5	10 ms	D	S	U	D	D	D	D	D	D	D	10.7%
6	5 ms	D	S	U	U	U	D	S	U	U	D	51.4%

### II. Power Class 3 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 3, all configurations (0-6) are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-2 below for results. The configuration determined in the results below was used to measure the MIF values in Table 7-6 and 7-8.

**Table 10-2**LTE TDD Power Class 3 UL-DL Configuration Results

	ETE TOO TOWER Glass & GE DE Gernigaration resoults														
Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons														
	20	40620	0	16QAM	1	0	Acoustic	6.89	16.76	-3.34	13.42	35.00	-21.58	M4	1,4,7
	20	40620	1	16QAM	1	0	Acoustic	6.02	15.59	-1.57	14.02	35.00	-20.98	M4	1,4,7
	20	40620	2	16QAM	1	0	Acoustic	4.59	13.24	1.48	14.72	35.00	-20.28	M4	1,4,7
LTE TDD / Band 41	20	40620	3	16QAM	1	0	Acoustic	5.21	14.33	-1.49	12.84	35.00	-22.16	M4	1,4,7
	20	40620	4	16QAM	1	0	Acoustic	4.93	13.85	0.68	14.53	35.00	-20.47	M4	1,4,7
	20	40620	5	16QAM	1	0	Acoustic	4.02	12.09	3.66	15.75	35.00	-19.25	M4	1,4,7
	20	40620	6	16QAM	1	0	Acoustic	6.62	16.41	-2.54	13.87	35.00	-21.13	M4	7,8,9

FCC ID: A3LSMF916U	POTEST: Proud to be post of the resources	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager		
Filename:	Test Dates:	DUT Type:		Dags 40 of 101		
1M2005200087-19-R1.A3L 07/13/2020 - 08/02/2020		Portable Handset		Page 42 of 101		

## III. Power Class 2 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 2, only configurations 1-5 are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-3 below for results. The configuration determined in the results below was used to measure the MIF values in Table 7-7.

**Table 10-3**LTE TDD Power Class 2 UL-DL Configuration Results

	ETE TBB T OWOT Glado E GE BE Goringaration recount														
Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons														
	20	40620	1	16QAM	1	0	Acoustic	11.46	21.18	-1.56	19.62	35.00	-15.38	M4	2,3,6
	20	40620	2	16QAM	1	0	Acoustic	8.19	18.27	1.53	19.80	35.00	-15.20	M4	2,6,9
LTE TDD / Band 41	20	40620	3	16QAM	1	0	Acoustic	9.90	19.91	-1.47	18.44	35.00	-16.56	M4	2,3,6
	20	40620	4	16QAM	1	0	Acoustic	8.44	18.53	0.73	19.26	35.00	-15.74	M4	2,3,6
	20	40620	5	16QAM	1	0	Acoustic	5.80	15.26	3.80	19.06	35.00	-15.94	M4	2,3,6

#### **IV. Conclusion**

Per the results above, UL-DL Configuration 5 was used for LTE TDD Power Class 3 and UL-DL Configuration 2 was used for LTE TDD Power Class 2 testing.

FCC ID: A3LSMF916U	Post ST.  Read to be post of the second HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 43 of 101
1M2005200087-19-R1.A3L 07/13/2020 - 08/02/2020		Portable Handset		Page 43 01 101

## 11. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSMF916U
S/N:	1113M

#### I. E-FIELD EMISSIONS:

**Table 11-1 HAC Data Summary for CDMA E-field** 

Mode	Channel	RC/SO	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissio	ns											
	564*	RC1/SO3	Acoustic	25.12	11.23	21.01	3.00	24.01	45.00	-20.99	M4	1,2,3
Cellular CDMA	1013	RC1/SO3	Acoustic	25.19	11.11	20.91	3.03	23.94	45.00	-21.06	M4	1,2,3
Celiulai CDIVIA	384	RC1/SO3	Acoustic	25.16	10.82	20.68	3.00	23.68	45.00	-21.32	M4	4,7,8
	777	RC1/SO3	Acoustic	25.13	12.65	22.04	3.04	25.08	45.00	-19.92	M4	4,7,8
	25	RC1/SO3	Acoustic	22.81	5.47	14.76	2.89	17.65	35.00	-17.35	M4	4,7,8
PCS CDMA	600	RC1/SO3	Acoustic	22.87	5.33	14.53	2.82	17.35	35.00	-17.65	M4	4,7,8
	1175	RC1/SO3	Acoustic	22.92	6.25	15.92	2.81	18.73	35.00	-16.27	M4	7,8,9

<sup>\*</sup> Note: Cellular CDMA ch.564 is the Part 90S test channel.

**Table 11-2** HAC Data Summary for CDMA E-field - Diversity Antenna

		-							0.0.0, 2		-		
Mode	Channel	RC/SO	Scan Center	Antenna	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons												
Cellular CDMA	777	RC1/SO3	Acoustic	Main A	25.13	12.65	22.04	3.04	25.08	45.00	-19.92	M4	4,7,8
Celiulai CDMA	777	RC1/SO3	Acoustic	Main B	23.30	3.28	10.31	3.04	13.35	45.00	-31.65	M4	7,8,9

**Table 11-3 HAC Data Summary for GSM E-field** 

			117	o Dutu	Gamma	ily for com E ficia							
Mode	Channel	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5		
E-Field Emission	ons												
	128	Acoustic	33.18	30.84	29.78	3.52	33.30	45.00	-11.70	M4	1,2,3		
GSM850	190	Acoustic	33.05	23.05	27.25	3.53	30.78	45.00	-14.22	M4	4,7,8		
	251	Acoustic	33.14	24.96	27.94	3.53	31.47	45.00	-13.53	M4	4,7,8		
	512	Acoustic	29.38	10.67	20.56	3.51	24.07	35.00	-10.93	M4	4,7,8		
GSM1900	661	Acoustic	28.89	11.98	21.57	3.51	25.08	35.00	-9.92	M4	7,8,9		
	810	Acoustic	29.20	12.28	21.78	3.51	25.29	35.00	-9.71	M4	7,8,9		

**Table 11-4 HAC Data Summary for GSM E-field - Diversity Antenna** 

Mode	Channel	Scan Center	Antenna	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons											
GSM850	128	Acoustic	Main A	33.18	30.84	29.78	3.52	33.30	45.00	-11.70	M4	1,2,3
GSIWIOSO	128	Acoustic	Main B	31.42	17.40	24.81	3.52	28.33	45.00	-16.67	M4	1,2,3

FCC ID: A3LSMF916U	PCTEST:	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 44 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Fage 44 01 101

## Table 11-5 HAC Data Summary for LTE TDD Band 41 Power Class 3 E-field

	11/10 Data Gammar j 10/ 212 133 Dama 11 1 Girol Glado G 2 1101a															
Mode / Band	(MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons															
	10	39750	5	16QAM	1	25	Acoustic	23.11	3.74	11.46	3.58	15.04	35.00	-19.96	M4	4,7,8
	10	40185	5	16QAM	1	25	Acoustic	23.30	5.47	14.75	3.40	18.15	35.00	-16.85	M4	7,8,9
LTE TDD / Band 41 PC3	10	40620	5	16QAM	1	25	Acoustic	23.37	4.84	13.70	3.67	17.37	35.00	-17.63	M4	2,3,6
	10	41055	5	16QAM	1	25	Acoustic	23.52	4.57	13.20	3.69	16.89	35.00	-18.11	M4	1,2,3
	10	41490	5	16QAM	1	25	Acoustic	23.54	4.02	12.07	3.58	15.65	35.00	-19.35	M4	2,3,6

## Table 11-6 HAC Data Summary for LTE TDD Band 41 Power Class 2 E-field

Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.		RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Ellissic			Ι.		Ι.	T -										
	15	39750	2	16QAM	1	0	Acoustic	26.32	5.18	14.28	1.46	15.74	35.00	-19.26	M4	4,7,8
	15	40185	2	16QAM	1	0	Acoustic	26.06	5.94	15.47	1.41	16.88	35.00	-18.12	M4	7,8,9
LTE TDD / Band 41 PC2	15	40620	2	16QAM	1	0	Acoustic	26.48	8.17	18.24	1.57	19.81	35.00	-15.19	M4	7,8,9
	15	41055	2	16QAM	1	0	Acoustic	26.23	7.91	17.96	1.57	19.53	35.00	-15.47	M4	2,3,6
	15	41490	2	16QAM	1	0	Acoustic	26.04	6.04	15.62	1.46	17.08	35.00	-17.92	M4	2,3,6

## Table 11-7 HAC Data Summary for LTE TDD Band 48 E-field

	· · · · · · · · · · · · · · · · · · ·															
Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons															
	5	55265	5	16QAM	1	0	Acoustic	22.69	8.81	18.90	3.52	22.42	35.00	-12.58	M4	2,3,6
LTE TDD / Band 48	5	55990	5	16QAM	1	0	Acoustic	22.67	7.67	17.69	3.57	21.26	35.00	-13.74	M4	2,3,6
	5	56715	5	16QAM	1	0	Acoustic	22.72	9.40	19.46	3.58	23.04	35.00	-11.96	M4	2,3,6

## Table 11-8 HAC Data Summary for NR TDD n41 E-field

Mode / Band	Bandwidth (MHz)	Channel	Waveform	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons															
NR TDD / n41	100	518598	DFT-s-OFDM	π/2-BPSK	270	0	Acoustic	23.46	17.10	24.66	1.34	26.00	35.00	-9.00	M4	2,3,6
NK TDD/ II41	100	518598	DFT-s-OFDM	π/2-BPSK	270	0	T-Coil	23.46	14.18	23.03	1.34	24.37	35.00	-10.63	M4	2,3,6

FCC ID: A3LSMF916U	PCTEST: Proad to be part of the secures	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 45 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 45 of 101

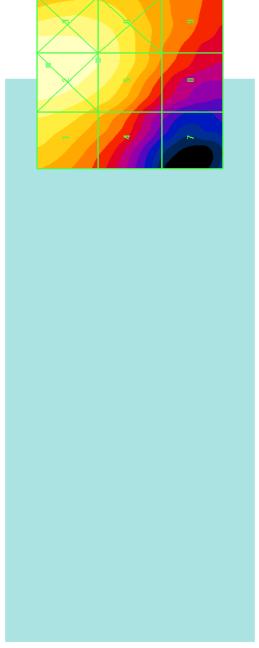


Figure 11-1
Sample E-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

FCC ID: A3LSMF916U	POTEST: Road to be post of the second HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 46 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 46 of 101

FCC ID:	A3LSMF916U
S/N:	1113M

## II. Worst-case Configuration Evaluation

Table 11-9
Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Bandwidth (MHz)	Channel	Waveform	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
Probe Rotation	at Worst-Case														
NR TDD / n41	100	518598	DFT-s-OFDM	π/2-BPSK	270	0	Acoustic	17.95	25.08	1.34	26.42	35.00	-8.58	M4	2,3,6

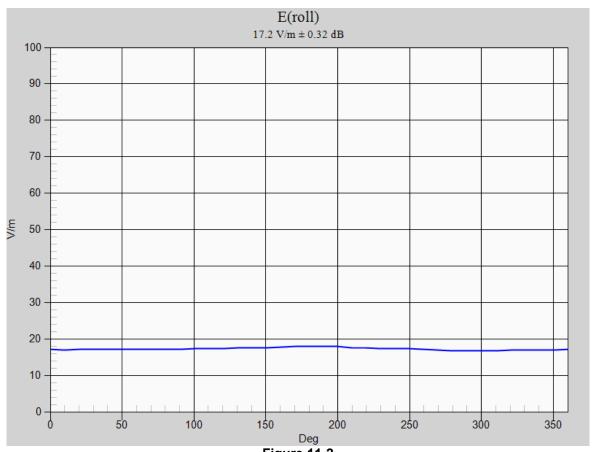


Figure 11-2
Worst-Case Probe Rotation about Azimuth axis

\* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

FCC ID: A3LSMF916U	Post ST.  Read to be post of the second HA	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 47 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 47 of 101

## 12. EQUIPMENT LIST

## **Table 12-1** Equipment List

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4438C	ESG Vector Signal Generator	3/11/2019	Annual	3/11/2021	MY45090700
Agilent	N5182A	MXG Vector Signal Generator	2/19/2020	Annual	2/19/2021	MY47420651
Keysight Technologies	N9020A	MXA Signal Analyzer	12/19/2019	Annual	12/19/2020	MY48010233
Amplifier Research	15S1G6	Amplifier	N/A	CBT*	N/A	433978
Anritsu	MA24106A	USB Power Sensor	2/27/2020	Annual	2/27/2021	1244524
Anritsu	MA24106A	USB Power Sensor	6/8/2020	Annual	6/8/2021	1344555
Anritsu	MA2411B	Pulse Power Sensor	12/4/2019	Annual	12/4/2020	1126066
Anritsu	MA2411B	Pulse Power Sensor	8/8/2019	Annual	8/8/2020	1339008
Anritsu	ML2496A	Power Meter	11/6/2019	Annual	11/6/2020	1405003
Control Company	4040	Temperature / Humidity Monitor	10/9/2018	Biennial	10/9/2020	181647812
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	CBT*	N/A	1226
Pasternack	PE2237-20	Bidirectional Coupler	N/A	CBT*	N/A	N/A
Rohde & Schwarz	CMW500	Wideband Radio Communication Tester	6/23/2020	Annual	6/23/2021	161662
Rohde & Schwarz	CMW500	Radio Communication tester	8/14/2019	Annual	8/14/2020	140144
SPEAG	AIA	Audio Interference Analzyer	N/A	CBT*	N/A	1010
SPEAG	EF3DV3	Freespace E-field Probe	1/16/2019	Biennial	1/16/2021	4035
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/19/2019	Biennial	2/19/2021	1003
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/19/2019	Biennial	2/19/2021	1137
SPEAG	CD2600V3	Freespace 2600MHz Dipole	2/19/2019	Biennial	2/19/2021	1012
SPEAG	CD3500V3	Freespace 3500 MHz Dipole	1/15/2019	Biennial	1/15/2021	1005
SPEAG	DAE4	Dasy Data Acquisition Electronics	2/12/2020	Annual	2/12/2021	665

Calibration traceable to the National Institute of Standards and Technology (NIST).

\*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

FCC ID: A3LSMF916U	POTEST: Proud to be post of the resources	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 40 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 48 of 101

#### 13. MEASUREMENT UNCERTAINTY

## **Table 13-1**Uncertainty Estimation Table

	Wireless Communications Device Near-Field Measurement						
		Uncer	tainty Estima	ation			
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
Measurement System	•		•			*	•
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	* Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.21	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	*
Test Sample Related							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)					0.66	16.3%	
Expanded Uncertainty [95% confidence]					1.31	32.6%	
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%

#### Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
  equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
  and NIST Tech Note 1297 and UKAS M3003.
- 2. \* Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

FCC ID: A3LSMF916U	POTEST Phote to the post of the second	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 49 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 49 01 101

## 14. TEST DATA

See following Attached Pages for Test Data.

FCC ID: A3LSMF916U	POTEST: Road to be part of the security	C (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Daga 50 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 50 of 101

Date: 7/13/2020



## **DUT: CD835V3 - SN1003**

Type: CD835V3 Serial: 1003

#### Communication System: CW; Frequency: 835 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):

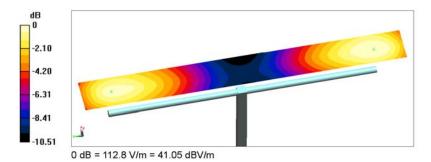
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 132.7 V/m; Power Drift = -0.04 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 111.5 V/m



FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 51 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Fage 51 01 101



## **DUT: CD1880V3 - SN1137**

Type: CD1880V3 Serial: 1137

#### Communication System: CW; Frequency: 1880 MHz;

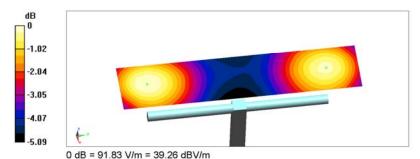
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 158.0 V/m; Power Drift = 0.01 dB Applied MIF = 0.00 dB Average Value of Peak (interpolated) = 90.7 V/m



FCC ID: A3LSMF916U	PCTEST:	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 52 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Fage 32 01 101

Date: 7/27/2020



## **DUT: CD1880V3 - SN1137**

Type: CD1880V3 Serial: 1137

#### Communication System: CW; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

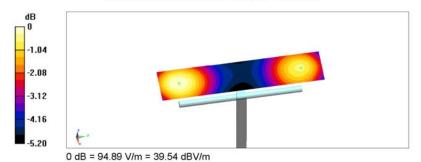
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 157.8 V/m; Power Drift = -0.10 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 91.9 V/m



FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 53 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 33 01 101

Date: 7/13/2020



## **DUT: CD2600V3 - SN1012**

Type: CD2600V3 Serial: 1012

#### Communication System: CW; Frequency: 2600 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

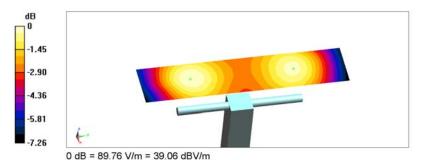
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 68.82 V/m; Power Drift = -0.04 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 88.3 V/m



FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags E4 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 54 of 101

Date: 7/27/2020



## **DUT: CD2600V3 - SN1012**

Type: CD2600V3 . Serial: 1012

#### Communication System: CW; Frequency: 2600 MHz;

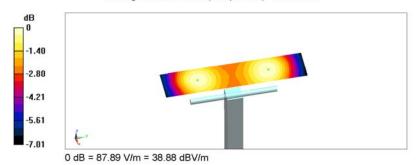
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 69.04 V/m; Power Drift = -0.04 dB Applied MIF = 0.00 dB Average Value of Peak (interpolated) = 87.8 V/m



FCC ID: A3LSMF916U	PCTEST .  Frond to be port of the summers	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg EE of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 55 of 101
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Date: 7/27/2020



## **DUT: CD3500V3 - SN1005**

Type: CD3500V3 Serial: 1005

#### Communication System: CW; Frequency: 3500 MHz;

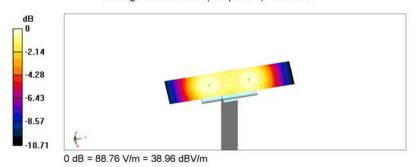
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### 3500 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 40.34 V/m; Power Drift = -0.12 dB Applied MIF = 0.00 dB Average Value of Peak (interpolated) = 87.9 V/m



FCC ID: A3LSMF916U	Post to be post of the second	IAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 56 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 30 01 101

Date: 7/17/2020



### DUT: A3LSMF916U

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:8

#### Communication System: CDMA; Frequency: 848.31 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

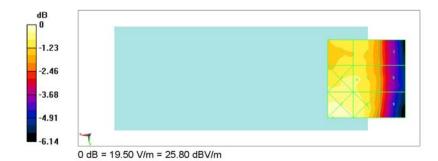
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### Cellular CDMA High Channel, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 16.16 V/m; Power Drift = 0.08 dB Applied MIF = 3.04 dB RF audio interference level = 25.08 dBV/m Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
24.81 dBV/m	24.84 dBV/m	23.8 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
25.1 dBV/m	25.08 dBV/m	23.88 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
25.8 dBV/m	25.39 dBV/m	23.83 dBV/m



FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 57 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 57 of 101

Date: 7/17/2020



#### **DUT: A3LSMF916U**

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:8

#### Communication System: CDMA; Frequency: 1908.75 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

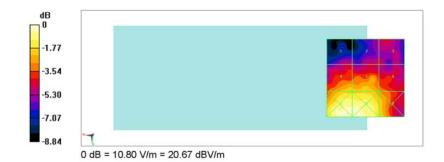
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### PCS CDMA High Channel, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 7.008 V/m; Power Drift = 0.16 dB
Applied MIF = 2.81 dB
RF audio interference level = 18.73 dBV/m
Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
15.99 dBV/m	16.04 dBV/m	16.11 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
18.68 dBV/m	18.73 dBV/m	17.82 dBV/m
Grid 7 <b>M4</b>	Grid 8 <b>M4</b>	Grid 9 <b>M4</b>
20.66 dBV/m	20.66 dBV/m	19.05 dBV/m



FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags E0 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 58 of 101



#### **DUT: A3LSMF916U**

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### GSM850 Low Channel, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 41.19 V/m; Power Drift = 0.17 dB
Applied MIF = 3.52 dB
RF audio interference level = 33.30 dBV/m
Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
33.62 dBV/m	33.95 dBV/m	33.18 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
33.09 dBV/m	33.3 dBV/m	32.76 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 <b>M4</b>
32.79 dBV/m	32.88 dBV/m	32.2 dBV/m



FCC ID: A3LSMF916U	POTEST: Plead to be port of the security	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 50 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 59 of 101



#### **DUT: A3LSMF916U**

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 1909.8 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

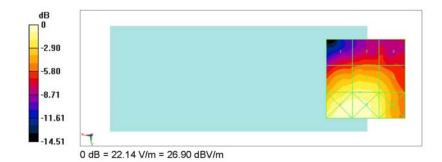
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

#### GSM1900 High Channel, Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 15.00 V/m; Power Drift = 0.01 dB
Applied MIF = 3.51 dB
RF audio interference level = 25.29 dBV/m
Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
20.78 dBV/m	21.31 dBV/m	21.08 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
25.21 dBV/m	25.29 dBV/m	24.49 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 M4
26.9 dBV/m	26.89 dBV/m	25.3 dBV/m



FCC ID: A3LSMF916U	Post ST.  Read to be post of the second HA	C (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 60 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 60 of 101

Date: 7/19/2020



#### **DUT: A3LSMF916U**

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:9.35

#### Communication System: LTE TDD41; Frequency: 2549.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

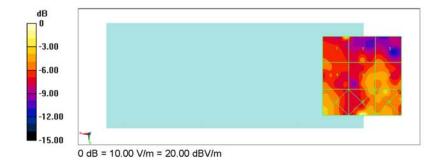
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## Power Class 3 TDD LTE Band 41 Low Mid Channel, UL-DL 5, 10MHz, 16QAM, 1RB, 25 RB Offset Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 4.462 V/m; Power Drift = 0.12 dB
Applied MIF = 3.40 dB
RF audio interference level = 18.15 dBV/m
Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
18.15 dBV/m	16.53 dBV/m	14.49 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
14.74 dBV/m	15.5 dBV/m	16.14 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 M4
17.27 dBV/m	21.22 dBV/m	16.46 dBV/m



FCC ID: A3LSMF916U	POTEST Phote to the post of the second	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 61 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 01 01 101

Date: 7/19/2020



#### **DUT: A3LSMF916U**

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:4.67

#### Communication System: LTE TDD41; Frequency: 2593 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

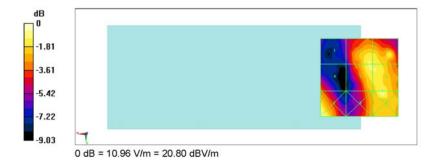
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## Power Class 2 TDD LTE Band 41 Mid Channel, UL-DL 2, 15MHz, 16QAM, 1RB, 0RB Offset Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 9.560 V/m; Power Drift = 0.15 dB
Applied MIF = 1.57 dB
RF audio interference level = 19.81 dBV/m
Emission category: M4

#### MIF scaled E-field

min coalea E ne		
Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
15.44 dBV/m	19.67 dBV/m	19.58 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
17.56 dBV/m	19.66 dBV/m	19.81 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 M4
20.79 dBV/m	18.65 dBV/m	19.99 dBV/m



FCC ID: A3LSMF916U	POTEST Post to be post of the common	IAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 62 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 02 01 101

Date: 7/29/2020



#### **DUT: A3LSMF916U**

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:9.35

#### Communication System: LTE Band 48; Frequency: 3697.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

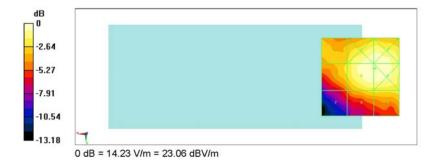
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## TDD LTE Band 48 High Channel, UL-DL 5, 5MHz, 16QAM, 1RB, 0RB Offset Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.96 V/m; Power Drift = 0.12 dB
Applied MIF = 3.58 dB
RF audio interference level = 23.04 dBV/m
Emission category: M4

#### MIF scaled E-field

min occioa E ne		
Grid 1 <b>M4</b>	Grid 2 <b>M4</b>	Grid 3 M4
20.54 dBV/m	22.95 dBV/m	22.99 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
20.83 dBV/m	23.04 dBV/m	23.06 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 M4
18.2 dBV/m	20.84 dBV/m	20.87 dBV/m



FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 62 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 63 of 101

Date: 8/2/2020



#### **DUT: A3LSMF916U**

Type: Portable Handset Serial: 1113M Backlight off Duty Cycle: 1:4

#### Communication System: n41; Frequency: 2593 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

#### DASY5 Configuration:

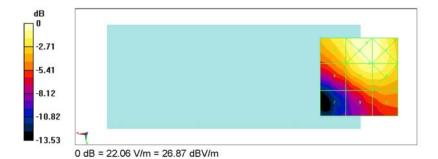
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

## TDD NR n41 Mid Channel, 100MHz, DFT-s-OFDM, π/2-BPSK, 270RB, 0RB Offset Acoustic Centered Scan/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 18.74 V/m; Power Drift = 0.06 dB
Applied MIF = 1.34 dB
RF audio interference level = 26.00 dBV/m
Emission category: M4

#### MIF scaled E-field

Grid 1 <b>M4</b>	Grid 2 M4	Grid 3 M4
25.35 dBV/m	26.87 dBV/m	26.71 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
23.69 dBV/m	26 dBV/m	25.95 dBV/m
Grid 7 <b>M4</b>	Grid 8 M4	Grid 9 M4
18.7 dBV/m	22.38 dBV/m	22.81 dBV/m



FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 64 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 64 of 101

#### CALIBRATION CERTIFICATES 15.

The following pages include the probe calibration used to evaluate HAC for the DUT.

FCC ID: A3LSMF916U	POTEST: Road to be part of the security	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo CE of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 65 of 101

#### Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage

Service suisse d'étalonnage
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Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client

PC Test

Certificate No: EF3-4035\_Jan19

### CALIBRATION CERTIFICATE

Object

EF3DV3-SN:4035

Calibration procedure(s)

QA CAL-02.v9, QA CAL-25.v7

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

January 16, 2019

2/1/2019

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature  $(22 \pm 3)^{\circ}$ C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: S5277 (20x)	04-Apr-18 (No. 217-02682)	Apr-19
DAE4	SN: 789	14-Jan-19 (No. DAE4-789_Jan19)	Jan-20
Reference Probe ER3DV6	SN: 2328	09-Oct-18 (No. ER3-2328_Oct18)	Oct-19
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-18)	In house check: Jun-20
Network Analyzer E8358A	SN: US41080477	31-Mar-14 (in house check Oct-18)	In house check; Oct-19

	Name	Function	Signature	
Calibrated by:	Manu Settz	Laboratory Technician		
Approved by:	Katja Pokovic	Technical Manager	Jak J	

Issued: January 17, 2019

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: EF3-4035\_Jan19

Page 1 of 8

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 66 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 66 of 101

#### Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage C Servizio svizzero di taratura **Swiss Calibration Service** 

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

NORMx,y,z sensitivity in free space DCP diode compression point

CF crest factor (1/duty\_cycle) of the RF signal A, B, C, D modulation dependent linearization parameters En incident E-field orientation normal to probe axis Εp incident E-field orientation parallel to probe axis

Polarization ω φ rotation around probe axis

Polarization 9 9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e.,  $\vartheta = 0$  is normal to probe axis

Connector Angle information used in DASY system to align probe sensor X to the robot coordinate system

### Calibration is Performed According to the Following Standards:

a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005

b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.1.1, May 2017

#### Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f  $\le 900$  MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- $NORM(f)x,y,z = NORMx,y,z * frequency\_response$  (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

Certificate No: EF3-4035 Jan19

Page 2 of 8

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 67 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 67 of 101

## DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

#### **Basic Calibration Parameters**

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (μV/(V/m)²)	0.90	0.74	1.20	± 10.1 %
DCP (mV) <sup>B</sup>	96.8	98.5	95.3	

Calibration results for Frequency Response (30 MHz = 6 GHz)

Frequency MHz	Target E-Field V/m	Measured E-field (En) V/m	Deviation E-normal in %	Measured E-field (Ep) V/m	Deviation E-normal in %	Unc (k=2) %
30	77.3	76.8	-0.6%	77.3	0.1%	± 5.1 %
100	77.3	78.2	1.2%	77.8	0.7%	± 5.1 %
450	77.1	78.2	1.5%	77.8	0.9%	± 5.1 %
600	77.1	77.8	0.9%	77.5	0.5%	± 5.1 %
750	77.3	77.7	0.5%	77.2	-0.1%	± 5.1 %
1800	140.3	136.9	-2.4%	137.2	-2.2%	± 5.1 %
2000	133.0	129.4	-2.8%	129.4	-2.7%	± 5.1 %
2200	124.8	121.5	-2.7%	122.7	-1.7%	± 5.1 %
2500	123.7	120.7	-2.4%	121.9	-1.5%	± 5.1 %
3000	78.8	74.8	-5.0%	76.1	-3.5%	± 5.1 %
3500	256.3	248.1	-3.2%	246.0	-4.0%	± 5.1 %
3700	249.7	239.2	-4.2%	239.0	-4.3%	± 5.1 %
5200	50.7	50.7	-0.1%	51.2	0.9%	± 5.1 %
5500	49.6	48.9	-1.5%	48.7	-1.9%	± 5.1 %
5800	48.9	49.1	0.4%	49.3	0.8%	± 5.1 %

Calibration Results for Modulation Response

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Max dev.	Unc <sup>±</sup> (k=2)
0	CW	Х	0.0	0.0	1.0	0.00	141.5	+ 3.3 %	±4.7 %
		Y	0.0	0.0	1.0		125.6		
		Y	0.0	0.0	1.0		125.1		

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: EF3-4035\_Jan19

Page 3 of 8

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 68 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 00 01 101

B Numerical linearization parameter: uncertainty not required.

E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the

## DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

### **Sensor Frequency Model Parameters**

	Sensor X	Sensor Y	Sensor Z
Frequency Corr. (LF)	0.28	0.21	5.68
Frequency Corr. (HF)	2.82	2.82	2.82

### **Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	57.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	335 mm
Probe Body Diameter	12 mm
Tip Length	25 mm
Tip Diameter	4 mm
Probe Tip to Sensor X Calibration Point	1.5 mm
Probe Tip to Sensor Y Calibration Point	1.5 mm
Probe Tip to Sensor Z Calibration Point	1.5 mm

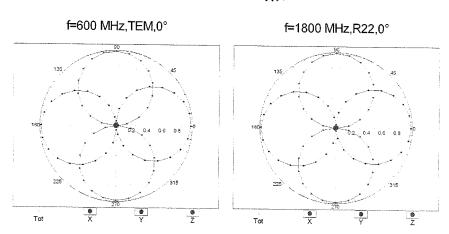
Certificate No: EF3-4035\_Jan19

Page 4 of 8

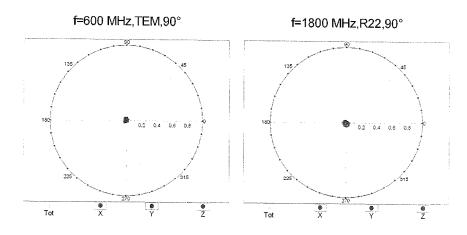
FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 69 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		3

EF3DV3 – SN:4035 January 16, 2019

## Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



## Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$

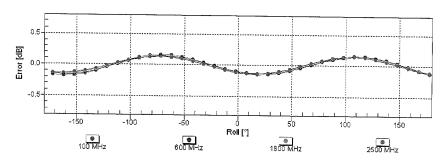


Certificate No: EF3-4035\_Jan19

Page 5 of 8

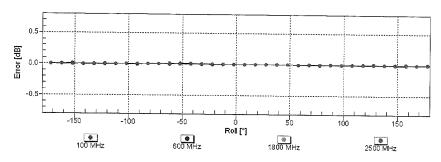
FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		Approved by: Quality Manager	
Filename:	Test Dates:	DUT Type:		Dags 70 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 70 of 101

## Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

## Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

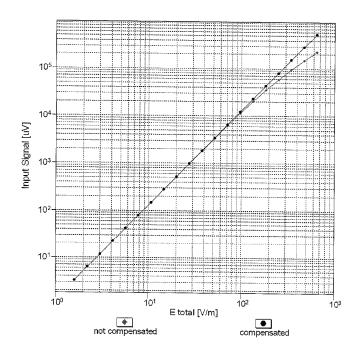
Certificate No: EF3-4035\_Jan19

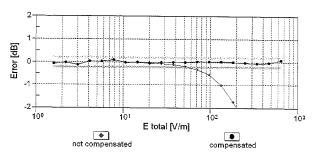
Page 6 of 8

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 71 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 71 of 101

EF3DV3 - SN:4035 January 16, 2019

# Dynamic Range f(E-field) (TEM cell, f = 900 MHz)





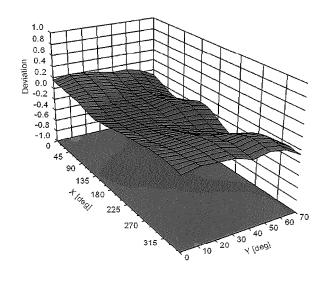
Uncertainty of Linearity Assessment: ± 0.6% (k=2)

Certificate No: EF3-4035\_Jan19 Page 7 of 8

FCC ID: A3LSMF916U	PCTEST: HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 72 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 72 01 101

EF3DV3 - SN:4035 January 16, 2019

# Deviation from Isotropy in Air Error $(\phi, \vartheta)$ , f = 900 MHz





Uncertainty of Spherical Isotropy Assessment:  $\pm$  2.6% (k=2)

Certificate No: EF3-4035\_Jan19

Page 8 of 8

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 72 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 73 of 101

# Calibration Laboratory of

Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland





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C Service suisse d'étalonnage
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The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client PC Test

Certificate No: CD835V3-1003\_Feb19

Object	CD835V3 - SN:	1003		
Calibration procedure(s)	QA CAL-20.v7 Calibration Procedure for Validation Sources in air			
Calibration date:	February 19, 20	19		
The measurements and the unce	ertainties with confidence p	ional standards, which realize the physical uniprobability are given on the following pages an ory facility: environment temperature ( $22 \pm 3$ )°C	d are part of the certificate.	
Primary Standards	ID#	Cal Date (Certificate No.)	Only delta to the sta	
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Scheduled Calibration Apr-19	
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19 Apr-19	
Daniel MDD 704		- '	Apr-19	
Power sensor NRP-Z91	I SIN: 103245	04-Δnr-18 (No. 217-02672)	A 40	
	SN: 103245 SN: 5058 (20k)	04-Apr-18 (No. 217-02673)	Apr-19	
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19	
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3	SN: 5058 (20k) SN: 5047.2 / 06327	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683)	Apr-19 Apr-19	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19	
Reference 20 dB Attenuator Type-N mismatch combination	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)	Apr-19 Apr-19 Jan-20 Jan-20	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4  Secondary Standards Power meter Agilent 4419B	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)  Check Date (in house) 09-Oct-09 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4  Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)  Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4  Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781  ID # SN: GB42420191 SN: US38485102	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)  Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4  Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781  ID # SN: GB42420191 SN: US38485102 SN: US37295597	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)  Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4  Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8358A	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781  ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477  Name	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)  Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18)	Apr-19 Apr-19 Jan-20 Jan-20  Scheduled Check In house check: Oct-20	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4  Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781  ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)  Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20	

Certificate No: CD835V3-1003\_Feb19

Page 1 of 5

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 74 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 74 of 101

### Calibration Laboratory of Schmid & Partner Engineering AG

Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

#### References

 ANSI-C63.19-2011
 American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids,

### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
  In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
  distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
  figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
  is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
  directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the
coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: CD835V3-1003\_Feb19 Page 2 of 5

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 75 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 75 of 101

### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

### Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	105.2 V/m = 40.44 dBV/m	
Maximum measured above low end	100 mW input power	105.1 V/m = 40.43 dBV/m	
Averaged maximum above arm	100 mW input power	105.2 V/m ± 12.8 % (k=2)	

# Appendix (Additional assessments outside the scope of SCS 0108)

### **Antenna Parameters**

Frequency	Return Loss	Impedance
800 MHz	17.6 dB	40.4 Ω - 7.2 jΩ
835 MHz	25.8 dB	52.2 Ω + 4.7 jΩ
880 MHz	16.9 dB	62.1 Ω - 10.5 jΩ
900 MHz	16.9 dB	52.2 Ω - 14.6  Ω
945 MHz	21.6 dB	51.8 Ω + 8.3 jΩ

### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

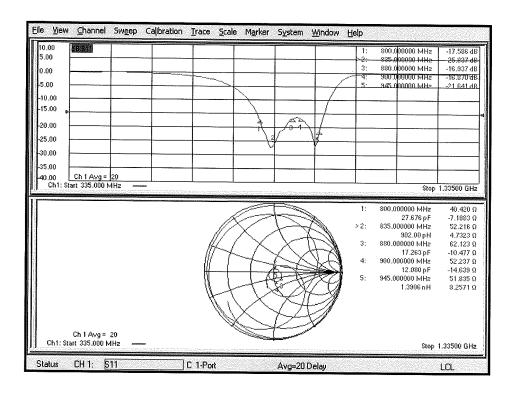
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD835V3-1003\_Feb19

Page 3 of 5

FCC ID: A3LSMF916U	PCTEST had to be part of the second	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 76 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 70 01 101

### **Impedance Measurement Plot**



Certificate No: CD835V3-1003\_Feb19

Page 4 of 5

FCC ID: A3LSMF916U	PCTEST:  HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 77 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage // or for

### **DASY5 E-field Result**

Date: 19.02.2019

Test Laboratory: SPEAG Lab2

### DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: $1003\,$

Communication System: UID 0 - CW; Frequency: 835 MHz Medium parameters used:  $\sigma = 0$  S/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup> Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

### DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 835 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

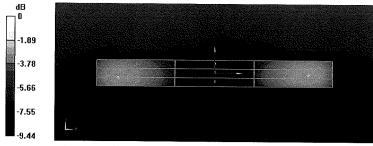
# Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 127.3 V/m; Power Drift = 0.04 dB Applied MIF = 0.00 dBRF audio interference level = 40.44 dBV/m

Emission category: M3

### MIF scaled E-field

Grid 1 M4	Grid 2 <b>M3</b>	Grid 3 M3
39.75 dBV/m	40.43 dBV/m	40.43 dBV/m
Grid 4 <b>M4</b>	Grid 5 M4	Grid 6 M4
35.35 dBV/m	35.75 dBV/m	35.73 dBV/m
Grid 7 <b>M3</b>	Grid 8 <b>M3</b>	Grid 9 <b>M3</b>
40.15 dBV/m	40.44 dBV/m	40.36 dBV/m



0 dB = 105.2 V/m = 40.44 dBV/m

Certificate No: CD835V3-1003\_Feb19

Page 5 of 5

FCC ID: A3LSMF916U	PCTEST HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 78 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 70 01 101

### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client

PC Test

Certificate No: CD1880V3-1137\_Feb19

Object	CD1880V3 - SN: 1137				
Calibration procedure(s)	QA CAL-20.v7 Calibration Procedure for Validation Sources in air				
Calibration date:	February 19, 20	19			
The measurements and the unce	ertainties with confidence p cted in the closed laborato	ional standards, which realize the physical ur probability are given on the following pages ar by facility: environment temperature ( $22 \pm 3$ )°	nd are part of the certificate.		
Primary Standards	ID #				
Power meter NRP	SN: 104778	Cal Date (Certificate No.)	Scheduled Calibration		
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672/02673)	Apr-19		
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19		
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02673)	Apr-19		
Type-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02682)	Apr-19		
Probe EF3DV3	SN: 4013	04-Apr-18 (No. 217-02683)	Apr-19		
DAE4	SN: 781	03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)	Jan-20 Jan-20		
Secondary Standards	ID#	Check Date (in house)	Scheduled Check		
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-17)	In house check: Oct-20		
Power sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Oct-17)	In house check: Oct-20		
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-17)	In house check: Oct-20		
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-17)	In house check: Oct-20		
Network Analyzer HP 8358A	SN: US41080477	31-Mar-14 (in house check Oct-18)	In house check: Oct-19		
	Name	Function	Signature		
Calibrated by:	Claudio Leubler	Laboratory Technician	Signature		
pproved by:	Katja Pokovic	Technical Manager	all L		

Certificate No: CD1880V3-1137\_Feb19

Page 1 of 7

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 79 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 19 01 101

### Calibration Laboratory of

Schmid & Partner **Engineering AG** Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage C Servizio svizzero di taratura S Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

#### References

ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by th
coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%

Certificate No: CD1880V3-1137 Feb19	Page 2 of 7	

FCC ID:	A3LSMF916U	PCTEST HAC (RF EMISSIONS) TEST REPORT		ST REPORT SAMSUNG	Approved by: Quality Manager
Filename	<b>)</b> :	Test Dates:	DUT Type:		Page 80 of 101
1M20052	00087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage ou oi iu i

### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

### Maximum Field values at 1730 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum 95.0 V/m = 39.55 dBV/m	
Maximum measured above high end	100 mW input power		
Maximum measured above low end	100 mW input power	94.9 V/m = 39.55 dBV/m	
Averaged maximum above arm	100 mW input power	95.0 V/m ± 12.8 % (k=2)	

### Maximum Field values at 1880 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	88.9 V/m = 38.98 dBV/m	
Maximum measured above low end	100 mW input power	86.6 V/m = 38.75 dBV/m	
Averaged maximum above arm	100 mW input power	87.8 V/m ± 12.8 % (k=2)	

Certificate No: CD1880V3-1137\_Feb19

Page 3 of 7

FCC ID: A3LSMF916U	PCTEST:	HAC (RE EMISSIONS) TEST REPORT		Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 91 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 81 of 101

### Appendix (Additional assessments outside the scope of SCS 0108)

### **Antenna Parameters**

#### **Nominal Frequencies**

Frequency	Return Loss	Impedance $54.4 \Omega + 6.5 j\Omega$	
1730 MHz	22.5 dB		
1880 MHz	21.1 dB	$55.9 \Omega + 7.2 j\Omega$	
1900 MHz	21.0 dB	$59.0 \Omega + 3.6 jΩ$	
1950 MHz	27.3 dB	53.0 Ω - 3.3 jΩ	
2000 MHz	20.3 dB	$42.4 \Omega + 4.8 j\Omega$	

### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

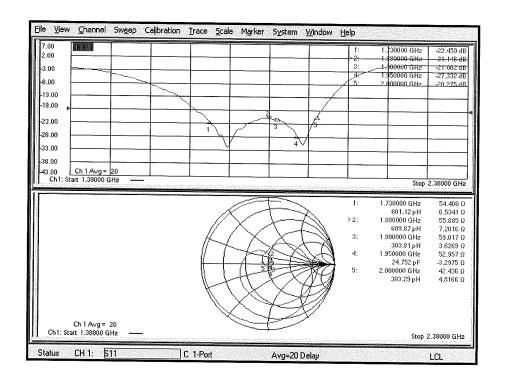
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD1880V3-1137\_Feb19 Page 4 of 7

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 82 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage oz or ioi

### **Impedance Measurement Plot**



Certificate No: CD1880V3-1137\_Feb19

Page 5 of 7

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 92 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 83 of 101

### **DASY5 E-field Result**

Date: 19.02.2019

Test Laboratory: SPEAG Lab2

# DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: UID 0 - CW; Frequency: 1880 MHz, Frequency: 1730 MHz

Medium parameters used:  $\sigma=0$  S/m,  $\epsilon_r=1;\, \rho=0$  kg/m  $^3$ 

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

### DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 1880 MHz, ConvF(1, 1, 1) @ 1730 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

# Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 151.5 V/m; Power Drift = 0.02 dB Applied MIF = 0.00 dBRF audio interference level = 38.98 dBV/m Emission category: M2

#### MIF scaled E-field

Grid 1 <b>M2</b>	Grid 2 <b>M2</b>	Grid 3 M2
38.55 dBV/m	38.98 dBV/m	38.93 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 M2
35.71 dBV/m	35.97 dBV/m	35.96 dBV/m
Grid 7 <b>M2</b>	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
38.31 dBV/m	38.75 dBV/m	38.73 dBV/m

Certificate No: CD1880V3-1137\_Feb19

Page 6 of 7

FCC ID: A3LSMF916U	POTEST Proof to the post of th	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 94 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 84 of 101

# Dipole E-Field measurement @ 1880MHz /E-Scan - 1730MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 165.0 V/m; Power Drift = 0.03 dB

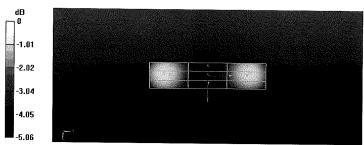
Applied MIF = 0.00 dB

RF audio interference level = 39.55 dBV/m

Emission category: M2

#### MIF scaled E-field

Grid 1 M2 39.09 dBV/m		Grid 3 M2
	Grid 5 <b>M2</b>	Grid 6 <b>M2</b>
	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>



0 dB = 88.87 V/m = 38.98 dBV/m

Certificate No: CD1880V3-1137\_Feb19

Page 7 of 7

FCC ID: A3LSMF916U	PCTEST:	IAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 85 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Fage 65 01 101

### **Calibration Laboratory of**

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Swiss Calibration Service

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Accreditation No.: SCS 0108

Client

PC Test

Certificate No: CD2600V3-1012\_Feb19

Object	CD2600V3 - SN	1012	
Calibration procedure(s)	QA CAL-20.v7 Calibration Proc	edure for Validation Sources in al	ir /0.4 3/19/
Calibration date:	February 19, 20	19	
This calibration certificate docum	nents the traceability to nat	ional standards, which realize the physical un	its of measurements (SI).
The measurements and the unce	ertainties with confidence p	robability are given on the following pages ar	nd are part of the certificate.
All calibrations have been condu	cted in the closed laborato	ry facility: environment temperature (22 $\pm$ 3)°C	C and humidity < 70%.
Calibration Equipment used (M&	TE critical for calibration)		
rimary Standards	ID#	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
ower sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19
Type-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02683)	Apr-19
Probe EF3DV3	SN: 4013	03-Jan-19 (No. EF3-4013_Jan19)	Jan-20
DAE4	SN: 781	09-Jan-19 (No. DAE4-781_Jan19)	Jan-20
Secondary Standards	ID #	Check Date (in house)	Salasta 100 d
Power meter Agilent 4419B	SN: GB42420191		Scheduled Check
Power sensor HP E4412A	SN: US38485102	09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	In house check: Oct-20
ower sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-17)	In house check: Oct-20
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-17)	In house check: Oct-20
letwork Analyzer HP 8358A	SN: US41080477	31-Mar-14 (in house check Oct-17)	In house check: Oct-20 In house check: Oct-19
	Name	Function	Signature
Calibrated by:	Claudio Leubler	Laboratory Technician	VX
	Katja Pokovic	Technical Manager	alle
pproved by:			

Certificate No: CD2600V3-1012\_Feb19

Page 1 of 5

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 96 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 86 of 101

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Accreditation No.: SCS 0108

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#### References

ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the
coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: CD2600V3-1012\_Feb19 Page 2 of 5

Ī	FCC ID: A3LSMF916U	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
	Filename:	Test Dates:	DUT Type:		Page 87 of 101
	1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage of or for

### **Measurement Conditions**

DASY system configuration, as far as not given on page 1

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	2600 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

### Maximum Field values at 2600 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum	
Maximum measured above high end	100 mW input power	85.6 V/m = 38.65 dBV/m	
Maximum measured above low end	100 mW input power	84.7 V/m = 38.56 dBV/m	
Averaged maximum above arm	100 mW input power	85.2 V/m ± 12.8 % (k=2)	

# Appendix (Additional assessments outside the scope of SCS 0108)

### **Antenna Parameters**

Frequency	Return Loss	Impedance	
2450 MHz	20.5 dB	42.7 Ω - 4.8 jΩ	
2550 MHz	32.1 dB	48.9 Ω + 2.2 jΩ	
2600 MHz	39.6 dB	50.3 Ω + 1.0 jΩ	
2650 MHz	30.4 dB	53.0 Ω + 0.9 jΩ	
2750 MHz	20.9 dB	48.9 Ω - 8.9 jΩ	

### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

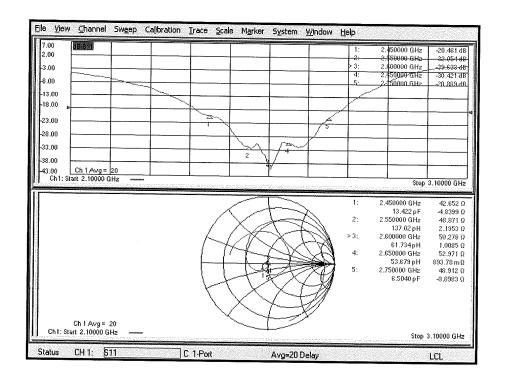
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD2600V3-1012\_Feb19 Page 3 of 5

FCC ID: A3LSMF916U	PCTEST had to be part of the second	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 88 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage oo or for

### **Impedance Measurement Plot**



Certificate No: CD2600V3-1012\_Feb19

Page 4 of 5

FCC ID: A3LSMF916U	PCTEST Proof to be post of the contents	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 89 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage og or for

### **DASY5 E-field Result**

Date: 19.02.2019

Test Laboratory: SPEAG Lab2

# DUT: HAC Dipole 2600 MHz; Type: CD2600V3; Serial: CD2600V3 - SN: 1012

Communication System: UID 0 - CW; Frequency: 2600 MHz Medium parameters used:  $\sigma = 0$  S/m,  $\epsilon_r = 1$ ;  $\rho = 0$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

### DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 2600 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

# Dipole E-Field measurement @ 2600MHz - with/E-Scan - 2600MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 62.82 V/m; Power Drift = -0.01 dB

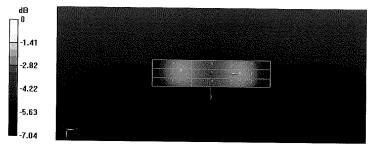
Applied MIF = 0.00 dB

RF audio interference level = 38.65 dBV/m

Emission category: M2

### MIF scaled E-field

Grid 1 M2	Grid 2 <b>M2</b>	Grid 3 <b>M2</b>
38.09 dBV/m	38.56 dBV/m	38.54 dBV/m
Grid 4 M2	Grid 5 <b>M2</b>	Grid 6 <b>M2</b>
37.82 dBV/m	38.06 dBV/m	38.02 dBV/m
Grid 7 <b>M2</b>	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
38.36 dBV/m	38.65 dBV/m	38.56 dBV/m



0 dB = 85.60 V/m = 38.65 dBV/m

Certificate No: CD2600V3-1012\_Feb19

Page 5 of 5

FCC ID: A3LSMF916U	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 90 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 90 01 101

### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Accreditation No.: SCS 0108

Client

C Test

Certificate No: CD3500V3-1005\_Jan19

CALIBRATION (	CERTIFICAT		Managhta a filippina farma a silar
Object	CD3500V3 - SN	1005	
Calibration procedure(s)	QA CAL-20.v7 Calibration Proce	edure for Validation Sources in ai	1 /0/4 2/11/2019
Calibration date:	January 15, 2019	9	
The measurements and the unce	ertainties with confidence p	ional standards, which realize the physical uniorobability are given on the following pages an ry facility: environment temperature $(22 \pm 3)^{\circ}$ C	d are part of the certificate.
Primary Standards	ID #	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19
Type-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02683)	Apr-19
Probe EF3DV3	SN: 4013	03-Jan-19 (No. EF3-4013_Jan19)	Jan-20
DAE4	SN: 781	09-Jan-19 (No. DAE4-781_Jan19)	Jan-20
Secondary Standards	'   ID #	Check Date (in house)	Scheduled Check
Power meter Agilent 4419B	SN: GB42420191	09-Oct-09 (in house check Oct-17)	In house check: Oct-20
Power sensor HP E4412A	SN: US38485102	05-Jan-10 (in house check Oct-17)	In house check: Oct-20
Power sensor HP 8482A	SN: US37295597	09-Oct-09 (in house check Oct-17)	In house check: Oct-20
RF generator R&S SMT-06	SN: 832283/011	27-Aug-12 (in house check Oct-17)	In house check: Oct-20
Network Analyzer HP 8358A	SN: US41080477	31-Mar-14 (in house check Oct-18)	In house check: Oct-19
,	Name	Function	Signature
,			~ N/2/3 /
ŕ	Leif Klysner	Laboratory Technician	Sel Illen
Calibrated by:		Laboratory Technician Technical Manager	5el Tillyn LLUS

Certificate No: CD3500V3-1005\_Jan19

Page 1 of 5

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dags 01 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 91 of 101

Calibration Laboratory of Schmid & Partner **Engineering AG** Zeughausstrasse 43, 8004 Zurich, Switzerland





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Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

#### References

[1] ANSI-C63.19-2011

Certificate No: CD3500V3-1005\_Jan19

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.	

Page 2 of 5

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		Approved by: Quality Manager	
Filename:	Test Dates:	DUT Type:		Page 92 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		1 490 02 01 101

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### **Measurement Conditions**

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	3500 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

### Maximum Field values at 3500 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	85.1 V/m = 38.60 dBV/m
Maximum measured above low end	100 mW input power	83.1 V/m = 38.39 dBV/m
Averaged maximum above arm	100 mW input power	84.1 V/m ± 12.8 % (k=2)

### Appendix (Additional assessments outside the scope of SCS 0108)

### **Antenna Parameters**

Frequency	Return Loss	Impedance
3300 MHz	22.2 dB	58.1 Ω + 2.1 jΩ
3400 MHz	29.7 dB	53.4 Ω - 0.3 jΩ
3500 MHz	25.4 dB	55.2 Ω - 2.4 jΩ
3600 MHz	22.1 dB	49.6 Ω - 7.8 jΩ
3700 MHz	19.7 dB	41.3 Ω - 3.6 jΩ

### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

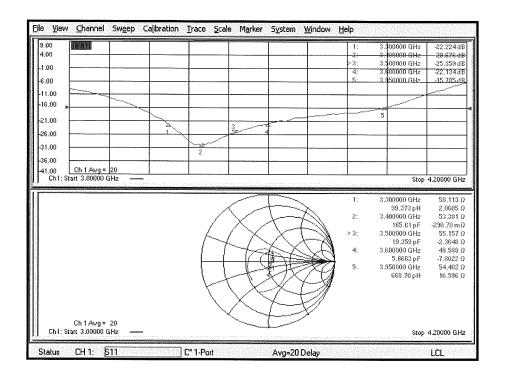
Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD3500V3-1005\_Jan19 Page 3 of 5

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Daga 02 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 93 of 101

### Impedance Measurement Plot



Certificate No: CD3500V3-1005\_Jan19 Page 4 of 5

FCC ID: A3LSMF916U	POTEST Product is a port of the second	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogo 04 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 94 of 101

### **DASY5 E-field Result**

Date: 15.01.2019

Test Laboratory: SPEAG Lab2

### DUT: HAC Dipole 3500 MHz; Type: CD3500V3; Serial: CD3500V3 - SN: 1005

Communication System: UID 0 - CW ; Frequency: 3500 MHz Medium parameters used:  $\sigma=0$  S/m,  $\epsilon_r=1$  ;  $\rho=0$  kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

### DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 3500 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

### Dipole E-Field measurement @ 3500MHz/E-Scan - 3500MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 34.54 V/m; Power Drift = 0.02 dB

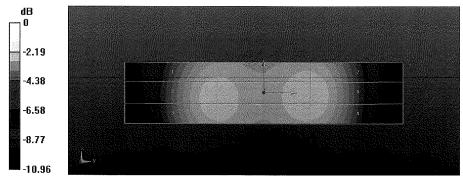
Applied MIF = 0.00 dB

RF audio interference level = 38.60 dBV/m

Emission category: M2

#### MIF scaled E-field

Grid 1 <b>M2</b>	Grid 2 <b>M2</b>	Grid 3 <b>M2</b>
38.08 dBV/m	38.39 dBV/m	38.38 dBV/m
Grid 4 <b>M2</b>	Grid 5 <b>M2</b>	Grid 6 <b>M2</b>
38.36 dBV/m	38.6 dBV/m	38.55 dBV/m
Grid 7 <b>M2</b>	Grid 8 <b>M2</b>	Grid 9 <b>M2</b>
38.35 dBV/m	38.60 dBV/m	38.54 dBV/m



0 dB = 85.13 V/m = 38.60 dBV/m

Certificate No: CD3500V3-1005\_Jan19

Page 5 of 5

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Dogg 05 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 95 of 101

#### CONCLUSION 16.

The measurements indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Daga 06 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Page 96 of 101

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FCC ID: A3LSMF916U	PCTEST  Proceed to the part of the second of		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 97 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		rage 97 01 101

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FCC ID: A3LSMF916U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
Filename:	Test Dates:	DUT Type:		Page 98 of 101
1M2005200087-19-R1.A3L	07/13/2020 - 08/02/2020	Portable Handset		Fage 96 01 101